

Electrodynamics of correlated electron systems:

Based on 2008 Boulder School for Condensed Matter and Materials Physics Lectures

N. P. Armitage

Department of Physics and Astronomy, The Johns Hopkins University, Baltimore, MD 21218, USA

(Dated: August 7, 2009)

Contents

I. Introduction	2
II. Formalism	5
A. Optical Constants of Solids	5
B. Classical Treatments: Drude-Lorentz	6
C. The Quantum Case	9
III. Techniques	11
A. Microwaves	11
B. THz spectroscopy	13
C. Infrared	15
D. Visible and Ultraviolet	16
IV. Examples	18
A. Simple Metals	18
B. Semiconductors and Band Insulators	19
C. Electron glasses	20
D. Mott insulators	22
E. Superconductors and other BCS-like states	23
V. Advanced Analysis	26
A. Sum Rules	26
B. Extended Drude Model	28
C. Frequency dependent scaling near quantum critical points.	33
VI. Acknowledgments	36
References	36

Physical and chemical systems can be characterized by their natural frequency ω and energy scales. It is hardly an exaggeration that most of what we know about such systems, from the acoustics of a violin to the energy levels of atoms, comes from their response to perturbations at these natural frequencies. For instance, chemists and biologists use infrared spectroscopy absorptions around 1650 cm^{-1} (which corresponds to frequencies of 49 THz, wavelengths of $6 \mu\text{m}$, and energies of 0.2 eV) to identify the carbon-carbon double bond in organic compounds. And it was the observation of light emission from atoms at discrete energies in the electron Volt (eV) range that led to the quantum theory.

It is of course the same situation in ‘correlated’ electron materials. We can learn about the novel effects of strong electron-electron interactions and the properties of collective states of matter (superconductors, quantum magnets etc.) by characterizing their response to small amplitude perturbations at their natural frequencies. In solids, these natural frequency scales span an impressively large frequency range from x-ray down to DC. This

incredibly broad range means that a blizzard of experimental techniques and analysis methods are required for the characterization of correlated systems with optical techniques.

This short review and lecture notes attempt to lay out a brief summary of the formalism, techniques, and analysis used for ‘optical’ spectroscopies of correlated electron systems. They are idiosyncratic, occasionally opinionated, and - considering the breadth of the subject - incredibly brief. Unfortunately, there is no single complete treatise that presents a complete background for these topics in the context of correlated electron materials. However, there are a number of excellent resources that collectively give a solid background to this field.

I recommend:

1. F. Wooten, “Optical Properties of Solids”, (Academic Press, New York, 1972).
The truly excellent and classic introduction to the subject of the electrodynamic response of solids (although there is very little in it in the way of electronic correlations). The book that multiple generations of spectroscopists learned from either directly or indirectly. To say that it is full of only basic obvious things is akin to complaining that Macbeth is full of quotations. Unfortunately it is out of print.... (1)
2. M. Dressel and G. Grüner, “Electrodynamics of Solids: Optical Properties of Electrons in Matter”, (Cambridge University Press, 2002).
Much newer and modern with many plots of relevant response functions. Good discussion of many important techniques (2).
3. G. D. Mahan, “Many-Particle Physics”, (Plenum, 2nd ed., 1990).
The go-to resource for perturbative treatments of correlations in solids (3). Excellent discussion of sum rules.
4. Richard D. Mattuck, “A Guide to Feynman Diagrams in the Many-Body Problem”, (Dover, 2nd ed., 1992).
It has been called “Feynman diagrams for dummies.” Well ... I like it anyways (4).
5. M. Tinkham, Introduction to Superconductivity, 2nd Ed., McGraw-Hill, NY, (1996).
The classic exposition on superconductivity. Excellent treatment of EM response of superconductors (and other BCS-like states) both from the phe-

nomenological two-fluid model and the full Mattis-Bardeen formalism (5).

6. E. van Heumen and D. van der Marel, "Salerno lectures: Optical probes of electron correlations in solids", Lecture notes for "XI Training Course in the Physics of Strongly Correlated Systems", Vietri sul Mare, Italy, 2-13 October 2006. Published in Lectures On The Physics Of Strongly Correlated Systems XI, Editors F. Mancini and A. Avella; Available at http://optics.unige.ch/vdm/marel_files/salerno_lectures.pdf
Very good lecture notes some of which parallels the treatment here (6).
7. D. van der Marel, "Optical signatures of electron correlations in the cuprates", "Strong interactions in low dimensions, Series: Physics and Chemistry of Materials with Low-Dimensional Structures" Vol. 25, 237-276 (2004); Also available at <http://arxiv.org/abs/cond-mat/0301506>
Excellent treatment of underlying theory, particularly that associated with various sum rules. Many relevant examples (7).
8. Andrew Millis, "Optical conductivity and correlated electron physics", "Strong interactions in low dimensions, Series: Physics and Chemistry of Materials with Low-Dimensional Structures" Vol. 25, 195-235 (2004); Also available at <http://phys.columbia.edu/~millis/july20.pdf>
Excellent review covering many aspects of the theory of optical measurements for correlated electron physics. Particularly good discussion on the use of sum rules. Explicit calculations within Kubo formalism. Many experimental examples with accompanying theoretical discussion. Unique treatment on the applicability of the conventional descriptions of the coupling of EM radiation to solids (8)
9. D. Basov and T. Timusk, "Electrodynamics of high- T_c superconductors", Reviews of Modern Physics **77**, 721 (2005).
A thorough review of the use of optical probes in the cuprate superconductors (9).
10. L. Degiorgi, "The electrodynamic response of heavy-electron compounds", Rev. Mod. Phys. **71**, 687 (1999).
11. A. Millis and P.A. Lee, "Large-orbital-expansion for the lattice Anderson model", Phys. Rev. B **35**, 3394 (1987).
Experimental and theoretical papers with excellent sections on the phenomenological expectations for the optical response of heavy fermion materials and optical self-energies (10; 11).
12. C.C. Homes, "Fourier Transform Infrared Spectroscopy", Lecture notes available here <http://infrared.phy.bnl.gov/pdf/homes/fir.pdf>
A good introduction to various technical issues associated with Fourier Transform Infrared Reflectivity (FTIR); the most commonly used measurement technique for optical spectra of correlated electron

systems (12).

13. George B. Arfken and Hans J. Weber, "Mathematical Methods for Physicists" (Academic Press, 2005).
The classic textbook of mathematical methods for physicists. Now with Weber. Good reference for Kramers-Kronig and Hilbert transforms (13).
14. John David Jackson, "Classical Electrodynamics" (3rd ed., Wiley, 1998).
No motivation need be given (14).

Other references as cited below.

I. INTRODUCTION

As mentioned above, the energy and frequency scales relevant for correlated systems span the impressive range of the x-ray down to DC (Fig. 1). For instance, atomic energy scales of 0.5 eV to the keV make solids possible through chemical bonding. These energies manifest themselves explicitly in correlations by, for instance, setting the energy scale of the large on-site repulsions U (1 - 10 eV) of electrons which can lead to Mott-Hubbard interactions and insulating states. Typical overlap integrals between atomic wavefunctions in solids are at the low end of the eV energy scale and set the scale of Fermi energies in metals and hence the energy scale for electron delocalization and roughly that also of plasmon collective modes. Various other collective modes such as phonons (lattice vibrations) and magnons (magnetic vibrations) are found at lower energy scales, typically at fractions of an eV. At energies of order 50 meV are the superconducting gaps of optimally doped cuprates. At even lower energies of the few meV scale the scattering rate of charges in clean metals is found. This is also the energy scales of gaps in conventional superconductors. Many local f -electron orbitals, which are relevant in Kondo materials are found at these energies. At even lower scales (approximately 10's of μ eV) can be found the width of the 'Drude' peaks found in the AC conductivity and the superconducting gaps of clean heavy fermion systems. Finally the 1 - 10 μ eV energy scale corresponds to the lowest temperatures typically reached with conventional cryogenics in the solid state (10 - 100 mK). The corresponding frequencies become important when studying crossover phenomena near quantum critical points with $\hbar\omega \approx k_B T$. All such energy scales can be studied in a number of different contexts with various photon spectroscopies.

Although there are many different photon spectroscopies that can be discussed, that span these scales, in these lectures I concentrate on 'optical' spectroscopies, which I define as techniques which involve transitions with net momentum transfer $q = 0$ and whose absorption and polarization properties are governed by the optical dipole matrix element. I do not discuss the fascinating and important work being done using other

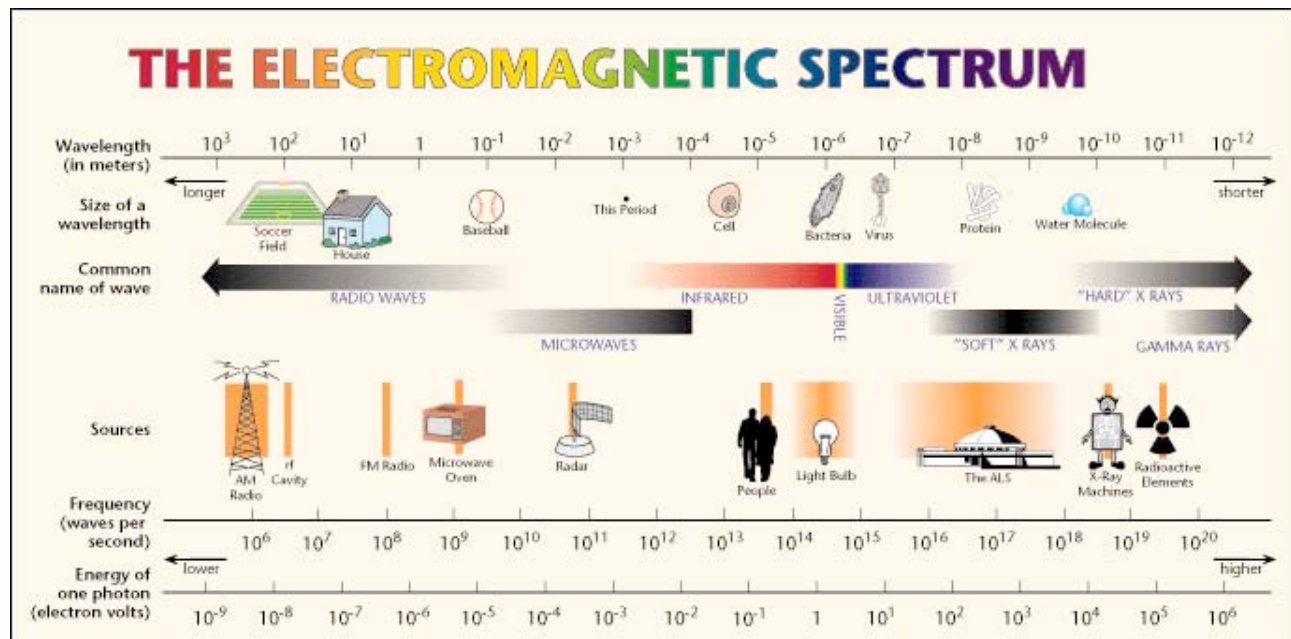


FIG. 1 (Color) The electromagnetic spectrum from radiofrequencies to gamma rays. Diagram from the LBL Advanced Light Source web site <http://www.lbl.gov/MicroWorlds/ALSTool/EMSpec/EMSpec2.html>.

photon spectroscopies using light and charge in correlated systems with for instance, Raman spectroscopy (15), electron energy loss, Brillouin scattering, optical Kerr rotation, photoemission, and fluorescence spectroscopies to give a tremendously very incomplete list. In the present case, the quantities of interest are typically the *complex* frequency dependent conductivity $\sigma(\omega)$ or dielectric constant $\epsilon(\omega)$. Alternatively data may be expressed in terms of one of a variety of straightforward complex parametrizations of these quantities like the index of refraction n and absorption coefficient k , or the complex surface impedance Z_s . These quantities are defined for the interaction of light with materials generically from zero frequency to arbitrarily high frequencies. In these lecture notes, however, I confine myself to the frequency range from microwaves, through the THz, to infrared, visible and ultraviolet. Each of these regimes gives different kinds of information and requires different techniques. For instance, microwaves are measured in cavities, striplines, or with Corbino techniques. THz is a huge growth area with the advent of time-domain THz and the increased use of Backward Wave Oscillators (BWOs). The infrared and visible range are measured by Fourier Transform Infrared Reflectivity (FTIR). Visible and Ultraviolet can be measured by grating spectrometers and spectroscopic ellipsometry. Of course there are large overlaps between all these regimes and techniques.

I caution that throughout these lecture notes, I frequently make use of the language of quasi-free electrons with well-defined masses and scattering times. It is not clear that such a description should be automatically valid in correlated systems. In fact, it is not even clear

that such a description should be valid in 'normal' materials. Why should an ensemble of 10^{24} electrons/cm³ interacting with each other *via* long range Coulomb interaction have excitations and states that resemble anything like those of free electrons? Naively one would expect that excitations would be manifestly many-electron composite objects wholly unrelated to the individual particles which constitute the system. It is nothing short of a miracle that, in fact, many materials are relatively well described by the assumption that interactions do not play a principle role in the explicit physics. Low-energy experiments (e.g. DC resistivity, heat capacity) on materials like sodium, gold, or silicon indicate that many aspects of such systems can be well described by free-electron physics. The largest affect on electrons appears to be the static field of the ionic cores and the average static effect of the other electrons. In other materials, like for instance the heavy fermion compounds, experiments seem to indicate that the charge carriers are free, but have masses many times larger than that of a bare electron. But even here at the lowest energy scales there are no explicit signs that charge carriers are simultaneously interacting with 10^{23} other charges and spins. In general, it is surprising that considering the close proximity that many electrons have to each other that such interactions appear to be only quantitative, but not qualitative perturbations on the free-electron physics.

In a system of interacting fermions, the relatively weak effect that even potentially strong interactions have on the underlying physics can be understood by realizing the strong constraint that Fermi statistics and a Fermi surface provides on the scattering kinematics. This phase

space constriction gives, within the conventional treatment, a scattering rate that goes like $\omega^2 + T^2$ at low frequency and temperature. Due to this quadratic dependence, for some small frequency the particle's scattering rate will be less than its energy and one can say that the quasi-particle excitation is well-defined and scattering is a minor perturbation on the free-electron physics. Such a perturbation renormalizes to zero in the $\omega \rightarrow 0$ limit. The effect of interactions can be subsumed into giving quasiparticle excitations a finite lifetime and a renormalized energy parameterized by an effective mass m^* .

Landau hypothesized that if one envisions slowly turning on an interaction potential in a gas of non-interacting electrons, some character of the original system would remain (16). Specifically, he conjectured that there would be a one-to-one correspondence between states and excitations of the non-interacting system and those of the interacting system. In which case there can be said to be an *adiabatic continuity* between the two and one can try to understand and model the interacting system by modeling the non-interacting one. A system with such a mapping is termed a *Fermi-liquid*. Its quasi-free electron-like excitations are termed *quasi-particles*.

The success of Fermi liquid theory comes from, as mentioned above, the constraint on scattering kinematics for low-energy excitations. This gives the result that quasi-particle excitations are only defined at arbitrarily small energy scales. The condition for well defined quasiparticles to exist, $\beta\omega^2 \ll \omega$, means that as one increases the parameter β , which characterizes the strength of electron-electron excitations, the maximum energy of well-defined excitations decreases, but well-defined quasiparticles will still exist at low energies. Within this view, stronger interactions mean only that Fermi liquid behavior will occur at lower-energy scales i.e. at lower temperatures and excitation energies.

Systems for which the Fermi-liquid paradigm is valid can be described at low energies and temperatures in terms of quasi-free electrons. Although the vast majority of normal metallic systems do seem to obey the Fermi liquid phenomenology, it is unclear whether such a description is valid for 'correlated' electron systems. A violation could occur for instance in Hubbard models when the intersite hopping parameter t , which parameterizes the band width, is much smaller than the onsite Coulomb interaction U resulting in an insulating state. So far however the fractional quantum Hall effect is the only case where Landau's conjecture regarding a one-to-one correspondence of states has been *experimentally* falsified (17; 18). On the theoretical side, exact solutions to 1D interacting models also show definitively that the fundamental excitations in 1D are not electron-like at all, but are fractions of electrons: spinons and holons that carry spin and charge separately (19). This would be another case where the electronic quasiparticle concept is not valid, but thus far in real systems the residual higher dimensionality has been found to stabilize the Fermi liq-

uid (See for instance Ref. (20))¹

It is true that many systems that we call strongly correlated exhibit a phenomenology inconsistent with the Fermi-liquid paradigm. It is unclear whether this is because interactions have driven such materials truly into a non-Fermi liquid state or because the Fermi liquid phenomena is obscured at the experimentally accessible temperatures and frequencies. For instance, it is important to keep in mind that the much heralded non-Fermi liquid behavior of high T_c cuprates is actually exhibited at relatively high temperatures (~ 100 K) above the occurrence of superconductivity. It may be that the inopportune occurrence of superconductivity obstructs the view of what would be the low-energy quasiparticle behavior.

At this point it is far from clear to what extent the Fermi liquid paradigm is valid in many of the materials being given as examples below. In this regard, one must keep in mind however, that despite the murky situation much of the language tossed around in this field presupposes the validity of it and the existence of well-defined electronic excitations. Indeed, much of the used terminology shows this bias. The terms 'density of states', 'effective mass', 'scattering rate', 'Pauli susceptibility', 'band structure', 'electron-phonon' coupling all require the context of the Fermi liquid to even make sense. Clearly such language is inappropriate if such excitations and states do not exist! Despite this, in the literature one sees many papers discussing, for instance, optical or photoemission electronic self-energies, while at the same time the authors discuss the non-Fermi liquid aspect of these materials. It is not clear whether it is appropriate to discuss electronic self-energies in materials where the elementary excitations are not electron-like. It is the case that while the formalism for generating electronic self-energies from optical or photoemission data as discussed below may be followed straightforwardly, the physical significance of such self-energies is not necessarily clear. For instance, although the parametrizations of optical spectra in terms of the frequency dependent mass and scattering rate from the extended Drude model (see below) can always be valid as a *parameterization*, it is reasonable that one can only assign physical significance to these quantities if the quasi-particle concept is valid in the energy range of interest.

Some aspects of the below formalism are model independent and some rests on the concept of well-defined electronic Fermi-liquid excitations. Although I will try to make the various distinctions clear, I use the language of

¹ Carbon nanotubes, which are in principle perfect 1D systems, have been claimed to have tunneling conductances that obey a voltage - temperature scaling that is consistent with Luttinger (1D) liquid physics (21). However there are serious questions whether this study showed scaling to the requisite precision in order to confirm a non-Fermi liquid nature. It may also be possible to account for the data in terms of temperature dependent Coulomb blockade (22).

quasi-free electrons almost entirely throughout the below, because at the very least it provides a rough intuition of the kinds of effects one expects in insulator, metals, and superconductors. It also provides a self-contained formalism for the analysis of optical spectra. A generalization of these ideas to strongly correlated systems does not currently exist. In the spirit of learning to walk before one learns to run, I use the language of quasi-free electrons in these lecture notes throughout, but I caution on the naive application of these ideas, which are only formally true for non-interacting systems to strongly interacting ones! The generalization to non-Fermi liquid, correlated, strongly interacting etc. etc. systems is left as an exercise for the reader!!!

II. FORMALISM

A. Optical Constants of Solids

Any discussion of the interaction of light with matter starts with Maxwell's equations

$$\nabla \cdot E(r, t) = 4\pi\rho(r, t), \quad (1)$$

$$\nabla \times E(r, t) = -\frac{1}{c} \frac{\partial}{\partial t} B(r, t), \quad (2)$$

$$\nabla \cdot B(r, t) = 0, \quad (3)$$

$$\nabla \times B(r, t) = \frac{1}{c} \frac{\partial}{\partial t} E(r, t) + \frac{4\pi}{c} J(r, t), \quad (4)$$

where E and B represent the electric and magnetic fields averaged over some suitable microscopic length (typically the incident light wavelength). As usual we introduce auxiliary fields as

$$D = E + 4\pi P, \quad (5)$$

$$H = B - 4\pi M, \quad (6)$$

where D and H have their conventional definitions and M and P are magnetization and polarization. Using the continuity equation for the electric current $\nabla \cdot J = -\frac{\partial \rho}{\partial t}$ and accounting for all sources for free conduction, polarization, and magnetization currents $J_{tot} = J_{cond} + \frac{\partial P}{\partial t} + c\nabla \times M$ as well as the external and induced charges $\rho_{total} = \rho_{ext} + \rho_{ind}$ we get the additional equations (please refer to Jackson (14) for a more extended discussion).

$$\nabla \cdot D = 4\pi\rho_{ext}, \quad (7)$$

$$\nabla \times H = \frac{1}{c} \frac{\partial D}{\partial t} + \frac{4\pi}{c} J_{ext} + \frac{4\pi}{c} J_{cond}. \quad (8)$$

Here we assume that we are in the linear regime and the response of polarization, or magnetization of current is linear in the applied field. We therefore write

$$\begin{aligned} P &= \chi_e E, \\ M &= \chi_m H, \\ J &= \sigma E. \end{aligned} \quad (9)$$

Typically we express the electric and magnetic susceptibilities in terms of dielectric functions $\epsilon = 1 + 4\pi\chi_e$ and magnetic permittivity $\mu = 1 + 4\pi\chi_m$. Except for explicitly magnetic materials, $\chi_m = 0$. The dielectric function (or its Fourier transform) is a response function that connects the field E at some time t and position r with the field D at some later time and position. Generally we first define it in the time and position domain *via* the relation

$$D(r, t) = \int_{-\infty}^t \int \hat{\epsilon}(r, r', t, t') E(r', t') d^3 r' dt'. \quad (10)$$

One could also describe the system's response in terms of current and conductivity $\hat{\sigma}(\omega)$

$$J(r, t) = \int_{-\infty}^t \int \hat{\sigma}(r, r', t, t') E(r', t') d^3 r' dt'. \quad (11)$$

In this context, the real space and time dependent $\hat{\epsilon}$ and $\hat{\sigma}$ are usually referred to as *memory* functions for obvious reasons. Note that the principle of causality is implied here; effects cannot precede their causes. For analysis of optical spectra we are typically more interested in their Fourier transforms $\sigma(q, \omega)$ and $\epsilon(q, \omega)$. This is because these are the quantities which are actually measured, but also because the mathematical complications of convolution in Eqs. 10 and 11 is avoided; convolution in the time-domain becomes multiplication in the frequency domain. The conductivity and dielectric function are related by²

$$\sigma = \frac{i\omega}{4\pi} (1 - \epsilon). \quad (12)$$

Given the very general form of Eqs. 10 and 11, simple physical considerations allow a number of general statements to be made. First, due to the vast mismatch between the velocity of light and the typical velocity of electrons in solids, we are typically concerned with the $q = 0$ limit of their Fourier transforms³. This means that except in a few circumstances, where one must take into

² One frequently sees the complex response function written using the real part of the conductivity and the real part of the dielectric function e.g. $\epsilon = \epsilon_1 + i4\pi\sigma_1/\omega$.

³ Alternatively one may say it is the $q = 0$ limit is relevant because of the large difference between the momentum carried by an 'optical' phonon and typical lattice momenta

account non-local electrodynamics, (very pure metals or clean superconductors for example), one can assume that down to the scale of some microscopic length there is a local relationship between the quantities given in Eqs. 9. This means that while these quantities may have spatial dependence (for instance the current J is confined to surfaces in metals), the proportionality expressed in Eqs. 9 holds. One can use the above expressions to rewrite Maxwell's equations explicitly in terms of ϵ , μ and σ . (Please see Jackson (14) for further details.)

Furthermore, the principle of causality - that effects can not proceed their causes - demands strict temporal considerations regarding the integrals in Eqs. 10 and 11. This leads to the powerful Kramers-Kronig relations relating the real and imaginary part of such response functions. We can rewrite Eq. 11 as

$$J(t) = \int_{-\infty}^t \hat{\sigma}(t-t')E(t')dt'. \quad (13)$$

From causality the conductivity memory function $\hat{\sigma}(t-t')$ has the property that $\hat{\sigma}(\tau < 0) = 0$ with $\tau = t - t'$. The Fourier transform of $\hat{\sigma}(t-t')$ is then

$$\sigma(\omega) = \int_0^t \hat{\sigma}(\tau)e^{i\omega\tau}d\tau. \quad (14)$$

The integral can be performed in the complex frequency plane with the substitution $\omega \rightarrow \omega_1 + i\omega_2$. It is then written

$$\sigma(\omega) = \int_0^\infty \hat{\sigma}(\tau)e^{i\omega_1\tau}e^{-\omega_2\tau}d\tau. \quad (15)$$

The factor $e^{-\omega_2\tau}$ in this integral is bounded in the upper half of the complex plane for $\tau > 0$ and in the lower half plane for $\tau < 0$. Since $\hat{\sigma}(\tau < 0) = 0$, this means that $\hat{\sigma}(\omega)$ is analytic for the upper half of the complex plane. This means that one can use Cauchy's theorem and therefore the relation

$$\oint \frac{\sigma(\omega')}{\omega' - \omega_0} d\omega' = 0 \quad (16)$$

holds in the usual way in the upper half of the complex plane. (Please see Wooten (1), Jackson (14) or Arfken (13) for further details on the integration and derivation of the Kramers-Kronig relations). One gets the expression

$$P \int_{-\infty}^{\infty} d\omega' \frac{\sigma(\omega')}{\omega' - \omega} - i\pi\sigma(\omega) = 0, \quad (17)$$

where P as usual denotes the principal part.

From this the Kramers-Kronig relations can be inferred. Using the fact that in the time-domain Im

$[\hat{\sigma}(\tau)] = 0$, which means that $\sigma(-\omega) = \sigma^*(\omega)$ we can write a simpler form of them as

$$\sigma_1 = \frac{2}{\pi} P \int_0^\infty d\omega' \frac{\omega' \sigma_2(\omega')}{\omega'^2 - \omega^2}, \quad (18)$$

$$\sigma_2 = -\frac{2\omega}{\pi} P \int_0^\infty d\omega' \frac{\sigma_1(\omega')}{\omega'^2 - \omega^2}. \quad (19)$$

The Kramers-Kronig relations are tremendously useful in the analysis and determination of optical spectra. When one knows one component of a response function for all frequencies, the other component automatically follows. As will be discussed below, they are used extensively in Fourier Transform Infrared Reflectivity (FTIR) measurements to determine the complex reflectivity (amplitude and phase) when only measuring reflected power.

The above discussion was based on some generalized frequency dependent conductivity $\sigma(\omega)$ and its model independent properties. In real materials, one has a zoo of different possible contributions to the electromagnetic response. For instance in simple metals with periodic translational symmetry (i.e. a crystal), one can identify a number of absorptions that satisfy the $q = 0$ constraint. For the schematic band structure shown in Fig. 2 (left), one expects a broad feature at finite energy (in red) in the optical conductivity (Fig. 2 (right)), which comes from the sum over all possible direct interband band absorptions (red arrow) in which electrons are promoted from below E_F across an energy gap to a higher lying band, with zero net momentum change. These are so-called vertical transitions. Near E_F absorptions with low but finite ω (green arrow) are only possible if strict translational symmetry has been broken by, for instance, disorder. Electrons moving in Bloch waves with mean free path ℓ , can violate strict momentum conservation in optical absorption at momentum scales on the order of $2\pi/\ell$. One can think of this heuristically as smearing out the band structure on this scale to allow vertical transitions within the same band. This gives a peak centered at zero frequency (in green). In the limit of perfect translational symmetry this peak would be a delta function centered at $\omega = 0$. One can also have excitations of harmonic waves of the lattice (phonons) if such phonons possess a net dipole moment in the unit cell. They appear as distinct and frequently very sharp peaks in the optical conductivity (in blue). Many different other excitations exist as well that can potentially be created *via* optical absorption.

Having introduced the general idea of optical response functions, I now discuss the derivation of them, both classically and quantum mechanically.

B. Classical Treatments: Drude-Lorentz

Almost the simplest model of charge conduction we can conceive of is of a single charge e of mass m , driven by an electric field E , and subject to a viscous damping

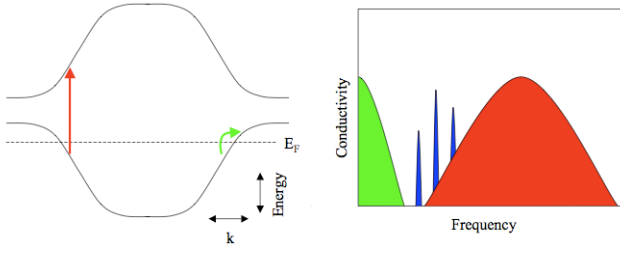


FIG. 2 (Color) Various different optical absorptions that satisfy the $q = 0$ constraint of optical spectroscopy can appear in the optical conductivity of simple metals. Near E_F intraband absorptions [green]. Interband absorptions [red]. Lattice vibrations (phonons) [blue] .

force that relaxes momentum on a time scale τ . Consider the force equation describing this situation

$$mx'' = -eE - mx'/\tau. \quad (20)$$

If we assume harmonic motion then $x = x_0 e^{-i\omega t}$ and $E = E_0 e^{-i\omega t}$. Substituting in for x and E and solving for x'_0 we get

$$x'_0 = \frac{e\tau E_0}{m} \frac{1}{1 - i\omega\tau}. \quad (21)$$

If we then consider an ensemble of such charges with density N , and realize that the maximum current density is $J_0 = Nex'_0$, we get the relation

$$J_0 = \frac{Ne^2\tau E_0}{m} \frac{1}{1 - i\omega\tau}. \quad (22)$$

Using the previously defined relation $J = \sigma E$ we find the relation for the frequency dependent ‘Drude’ conductivity is

$$\sigma(\omega) = \frac{Ne^2\tau}{m} \frac{1}{1 - i\omega\tau} = \frac{Ne^2\tau}{m} \frac{1 + i\omega\tau}{1 + \omega^2\tau^2}. \quad (23)$$

Interestingly, this classical model, first conceived of by Paul Drude, is actually of great use even in the analysis of particles obeying quantum mechanical statistics. As discussed below one finds the same functional form to leading order in that case as well.

The Drude model (plotted in Fig. 3) demonstrates a number of important features that are found generally in response functions. Its limit at $\omega \rightarrow 0$ is $Ne^2\tau/m$ is well behaved mathematically and equivalent to the DC value. As shown in Fig. 3, it has real and imaginary components that differ from each other. At low frequency the current’s response is in phase with the driving field and purely dissipative (real). At intermediate frequencies (when the driving frequency is of order the scattering rate $1/\tau$), the real conductivity falls to half its DC

value and imaginary conductivity peaks and equals the real value. At higher frequencies, two things happen. Not only does the current begin to lag the driving field, but its overall magnitude decreases as the response has a harder time keeping up with the driving electric field. The conductivity also exhibits distinct power laws in its various frequency limits: linear for the imaginary part at low ω , $1/\omega$ at high ω , and $1/\omega^2$ for the real part at high frequency.

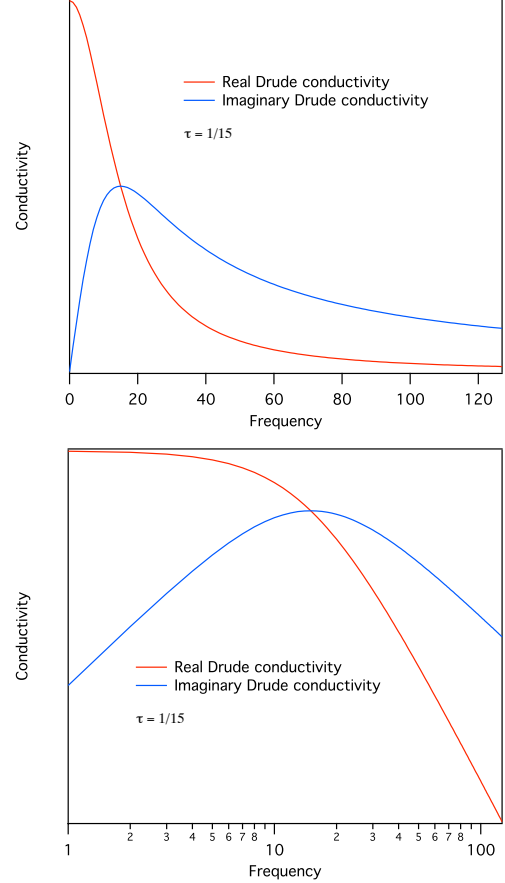


FIG. 3 (Color) Frequency dependent Drude conductivity with scattering rate $1/\tau = 15$ on linear scale (top) log-log scale (bottom).

In the limit of zero dissipation $1/\tau \rightarrow 0$ Equation 23 has the limiting form

$$\sigma_1 = \frac{\pi}{2} \frac{Ne^2}{m} \delta(\omega = 0), \quad (24)$$

$$\sigma_2 = \frac{Ne^2}{m\omega}. \quad (25)$$

σ_1 is zero everywhere, but at $\omega = 0$. As σ_1 is proportional to dissipation, this demonstrates that a gas of collisionless electrons cannot absorb photons at finite frequency. This can be shown directly by demonstrating that the Hamiltonian that describes this interaction,

commutes with the momentum operator p and hence it has no time dependence. With the exception of umklapp scattering, electron-electron interactions do not change this situation, as such interactions cannot degrade the total system momentum.

The dependence of the Drude conductivity on τ , N , and m , shows that the optical mass of charge carriers in metals can be obtained if for instance the charge density is known from other parameters like the Hall coefficient. For instance, in Fig. 4 the mass determined by optical conductivity is plotted against the linear coefficient in the specific heat (which is proportional to the electronic density of states and hence the mass). From simple metals to exotic heavy fermion materials, it shows a dramatic linear dependence over 3 orders of magnitude.

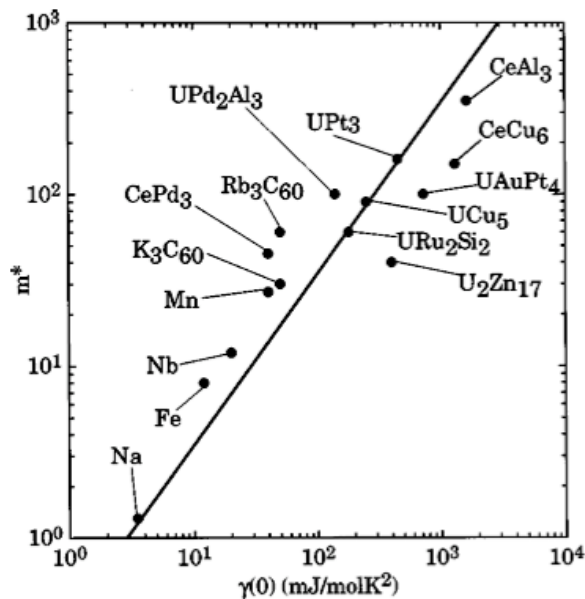


FIG. 4 (Color) Specific-heat values γ vs effective mass m^* , evaluated from the optical data using spectral-weight arguments (23)

It is convenient to express the prefactors of the Drude conductivity in terms of the so-called *plasma frequency* $\omega_p = \sqrt{\frac{4\pi N e^2}{m}}$. The plasma frequency is equivalent to the frequency of the free longitudinal oscillations of the electron gas⁴. The conductivity can be expressed

$$\sigma(\omega) = \frac{\omega_p^2}{4\pi} \frac{\tau}{1 - i\omega\tau}. \quad (26)$$

⁴ In actual materials, high energy excitations give a contribution to the dielectric function ϵ_∞ that renormalizes the observed plasma frequency downward to the *screened* plasma frequency $\sqrt{\frac{4\pi N e^2}{m\epsilon_\infty}}$. This is the actual frequency of plasmon oscillations in a real material.

Therefore within the Drude model, the optical response is fully determined by two frequencies: the plasma frequency ω_p and the scattering rate $1/\tau$. Since ω_p is many orders of magnitude greater than $1/\tau$, this allows us to define three distinctly different regimes for the optical response.

At low frequencies $\omega \ll 1/\tau$, in the so-called *Hagen – Rubens* regime, the conductivity is almost purely real, frequency independent, and approximately equal to the DC value. At intermediate frequencies, in the *relaxation regime* where ω is on the order of $1/\tau$, one must explicitly take into account the $\omega\tau$ factor in the denominator of Eq. 23. As mentioned above when $\omega = 1/\tau$ the real conductivity falls to half its DC value and the imaginary conductivity peaks and is equal to the real value⁵. The significance of the high frequency regime $\omega > \omega_p$ can be seen in rewriting the conductivity as the dielectric function. It is

$$\epsilon(\omega) = 1 - \frac{\omega_p^2}{\omega^2 - i\omega/\tau}. \quad (27)$$

The real and imaginary parts of this expression are given in Fig. 5. One sees that for the conventional case where $\omega_p \gg 1/\tau$, the plasma frequency is the frequency at which the real part of the dielectric function changes sign from negative to positive i.e. ω_p sets the scale for the zero crossing of ϵ_1 . An analysis of the reflection and transmission using the *Fresnel* equations (see Jackson (14)), shows that above the zero crossing, metals described by the Drude model become transparent. Hence this high frequency limit is called the *transparent* regime.

Despite its classical nature, the Drude model describes the gross features of many metals quite well at low frequencies. We give a number of examples of its use and extensions below. Of course, our interest in the electrodynamics of solids extends far beyond the case of simple metals. We will find the Drude model lacking in this regard. And even for ‘simple’ metals, one has the interesting aspects of finite frequency absorptions that parameterize band structure and, for instance, give copper and gold their beautiful colors. The Drude model is wholly inadequate to describe such finite frequency absorptions. For such processes in more complicated metals, semiconductors, and insulators, one can model them quantum mechanically in a number of ways, but we can also gain predictive power and intuition from an extension to the classical Drude model called *Drude-Lorentz*.

Here we envision the electrons are additionally also subject to a simple harmonic restoring force $-Kx$. Of course, such a model is *physically* inadequate to describe

⁵ Of course in real materials, there are interband excitations which can also contribute to the conductivity. The Drude model as presented here is an idealized case.

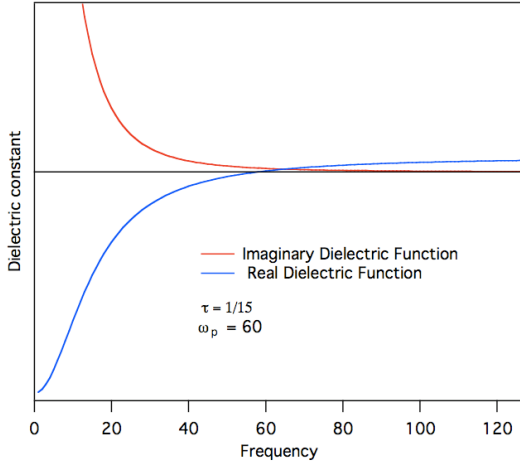


FIG. 5 (Color) Frequency dependent Drude dielectric function with scattering rate $1/\tau = 15$ and plasma frequency $\omega_p = 60$. The real part of the dielectric function changes sign at ω_p .

finite frequency absorption in most band semiconductors and insulators, as their insulating nature is due to the properties of filled bands and not electron localization. Nevertheless, numerous aspects of absorption at ‘band-edges’ in semiconductors can be modeled phenomenologically with Drude-Lorentz. Of course its applicability to the modeling of harmonic phonon absorptions is obvious.

With $\omega_0^2 = K/m$, we extend Eq. 20 as

$$mx'' = -eE - mx'/\tau - \omega_0^2 x, \quad (28)$$

Proceeding in exactly the same fashion as for the simple Drude model, we obtain for the Drude-Lorentz conductivity

$$\sigma(\omega) = \frac{Ne^2}{m} \frac{\omega}{i(\omega_0^2 - \omega^2) + \omega/\tau}, \quad (29)$$

One can see that in the limit $\omega_0 \rightarrow 0$ the Drude relation is obtained.

As mentioned above, despite its classical nature and the inapplicability of the underlying physical picture for some situations, in some cases the Drude-Lorentz model can be used to quantify finite frequency absorptions. In the case of the band edge absorption in semiconductors, a number of oscillators of the form of Eq. 29 with different weights can be used to capture the decidedly non-Lorentzian line shape. One can convince oneself that since any lineshape can be fit arbitrarily well using an arbitrarily large number of oscillators and moreover since the imaginary part of the response follows from a Kramers-Kronig transform of the real part, it is always perfectly feasible to parametrize the response using Drude-Lorentz.

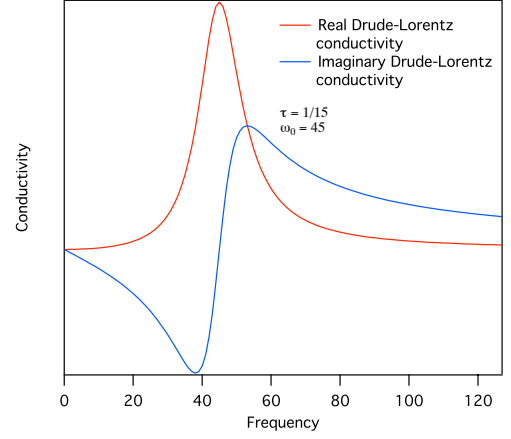


FIG. 6 (Color) Frequency dependent Drude-Lorentz complex conductivity with scattering rate $1/\tau = 15$ and oscillator resonant frequency $\omega_0 = 45$. The real conductivity is zero at $\omega = 0$ and positive for all frequencies.

C. The Quantum Case

The above Drude and Drude-Lorentz models are classical models used to describe intrinsically quantum mechanical phenomena and the fact that they are useful at all to describe solids is surprising. It is clear that a quantum mechanical treatment is desired. The most commonly used method for the quantum mechanical calculation of electromagnetic response of materials is the *Kubo* formalism. It is based on the fluctuation-dissipation theorem, which relates the spontaneous fluctuations of a system described *via* its correlation functions to its driven linear response. The derivation here loosely follows the one of Wooten (1) and Dressel and Grüner (2).

We calculate conductivity, by calculating the absorption rate of a system based on the power dissipated $P = \sigma_1 E^2$. We first use Fermi’s Golden rule to calculate the scattering probability that incident radiation excites an electron from one state $|s\rangle$ to another $|s'\rangle$

$$W_{s \rightarrow s'} = \frac{2\pi}{\hbar^2} |\langle s' | H_i | s \rangle|^2 \delta(\omega - \omega_{s'} + \omega_s). \quad (30)$$

$|s\rangle$ and $|s'\rangle$ are the system’s eigenstates, which may include the effects of many body physics. The interaction Hamiltonian for charge with the electromagnetic field to first-order in field is

$$H_i = \frac{e}{2mc} \sum_{i=1}^N [p_i \cdot A(r_i) + A(r_i) \cdot p_i] - e \sum_{i=1}^N \Phi(r_i), \quad (31)$$

where p , A , and Φ are the quantum mechanical operators for momentum, vector potential, and scalar potential and c is the speed of light. Since the vector potential A depends on position, it does not in general commute

with p . However since $p = -i\hbar\nabla$, one can show that $p \cdot A - A \cdot p = -i\hbar\nabla \cdot A$ and since within the Coulomb gauge $\nabla \cdot A = 0$, p and A can in fact commute. This means that for purely transverse waves with $\Phi = 0$ the interaction Hamiltonian simplifies to

$$H_i^T = \frac{e}{mc} \sum_{i=1}^N p_i \cdot A(r_i). \quad (32)$$

By substituting in for the canonical momentum $p = mv - eA/c$, dropping all terms that are higher than linear in A , and replacing the summations by an integral one H_i takes the form

$$H_i^T = -\frac{1}{c} \int dr J^T(r) \cdot A^T(r). \quad (33)$$

This gives a Fourier transformed quantity of

$$H_i^T = -\frac{1}{c} J^T(q) \cdot A^T(q). \quad (34)$$

This means we can substitute in for the form of H_i in the expression for $W_{s \rightarrow s'}$ to get

$$W_{s \rightarrow s'} = \frac{2\pi}{\hbar^2} |\langle s' | H_i^T | s \rangle|^2 \delta(\omega - \omega_{s'} + \omega_s). \quad (35)$$

The matrix element in this expression follows from the form of H_i^T . It is

$$\langle s' | H_i^T | s \rangle = -\frac{1}{c} \langle s' | J^T(q) | s \rangle A^T(q). \quad (36)$$

which leads to

$$W_{s \rightarrow s'} = \frac{2\pi}{\hbar^2 c^2} \langle s' | J^T(q) | s \rangle \langle s | J^{T*}(q) | s' \rangle, \quad (37)$$

$$|A^T(q)|^2 \delta(\omega - \omega_{s'} + \omega_s).$$

where $J^{T*}(q) = J^T(-q)$. One then sums over all occupied initial and all empty final states $W = \sum_{s,s'} W_{s \rightarrow s'}$. The dissipated power per unit time and volume at a particular photon frequency ω follows after a few mathematical steps as

$$P = \hbar\omega W = \quad (38)$$

$$|A^T(q)|^2 \sum_s \frac{\omega}{\hbar c^2} \int dt \langle s | J^T(q, 0) J^{T*}(q, t) | s \rangle e^{-i\omega t}.$$

The electric field is related to the vector potential as $E^T = i\omega A^T/c$ for transverse waves. Upon substitution we get the absorbed power per unit volume per unit time expressed as a current-current correlation function

$$P = |E^T(q)|^2 \sum_s \frac{1}{\hbar\omega} \int dt \langle s | J^T(q, 0) J^{T*}(q, t) | s \rangle e^{-i\omega t} \quad (39)$$

Using our previously given relation $P = \sigma_1 E^2$, the expression for the real part of the conductivity is

$$\sigma_1^T(q, \omega) = \sum_s \frac{1}{\hbar\omega} \int dt \langle s | J^T(q, 0) J^{T*}(q, t) | s \rangle e^{-i\omega t}. \quad (40)$$

The imaginary part of $\sigma(\omega)$ follows from the Kramers-Kronig relation. This is the *Kubo* formula. It has the form expected for the fluctuation-dissipation theorem, that of a correlation function (here current-current) averaged over all the states $|s\rangle$ and describes fluctuations of the current in the ground state. The conductivity depends on the time correlation between current operators integrated over all times.

The above formalism is general and applies to any set of system states $|s\rangle$. An extension can be made in cases where Fermi statistics applies. The end result is (see Dressel and Grüner (2) for the full derivation)

$$\sigma_1^T(\omega) = \frac{\pi e^2}{m^2 \omega} \frac{2}{(2\pi)^3} |\langle s' | p | s \rangle|^2 D_{s's}(\hbar\omega). \quad (41)$$

Here $\langle s' | p | s \rangle$ is known as the dipole matrix element. $D_{s's}$ is the so-called joint density of states, defined as $\frac{2}{(2\pi)^3} \int \delta(\hbar\omega - \hbar\omega_{s's}) dk$. This equation, which is often referred to as the *Kubo-Greenwood* formula, is extremely useful for the calculation of higher lying interband transitions in metals and semiconductors when the states $|s\rangle$ and $|s'\rangle$ belong to different bands (as for instance illustrated by the red arrow in Fig. 2). It also has the form that one may naively expect; it is proportional to the joint density of states and a matrix element which incorporates aspects like symmetry constraints and selection rules for allowed transitions.

We can use the Kubo formalism (Eq. 40) to calculate the leading order metallic conductivity in a slightly more rigorous fashion than was done in the classical approach above. We start with Eq. 40 and then posit as an ansatz that finite currents relax as

$$J(q, t) = J(q, 0) e^{-t/\tau}. \quad (42)$$

and assume that the current correlation time τ has no dependence on q . Inserting this into the Kubo formula, one gets that

$$\sigma_1(q, \omega) = \frac{1}{\hbar\omega} \sum_s \int dt e^{-i\omega t - |t|/\tau} \langle s | J^2(q) | s \rangle. \quad (43)$$

One now needs an expression for the current fluctuations at finite q . The expectation value for J is zero,

but fluctuations lead to a finite value of $\langle J^2 \rangle$. For small q , one can show in the ‘dipole approximation’ that $J(q) = -\frac{e}{m} \sum_i p_i$ where i labels the individual charges. With the reinjection of a complete set of states s' one gets the expression

$$\sigma_1(q, \omega) = \frac{e^2}{m^2 \hbar \omega} \int dt e^{-i\omega t - |t|/\tau} \sum_{s, s', i} |\langle s' | p_i | s \rangle|^2. \quad (44)$$

The quantity $2 \sum_{s, s', i} \frac{|\langle s' | p_i | s \rangle|^2}{m \hbar \omega_{s, s'}}$ found in Eq. 44 is called the *oscillator strength* $f_{s, s'}$. Here ω in Eq. 44 is the energy difference between states $|s\rangle$ and $|s'\rangle$ as is $\omega_{s, s'}$ in the definition of the oscillator strength. Below, we pay special attention to the oscillator strength when we calculate the optical sum rules.

The oscillator strength can be easily calculated for the case of free electrons where the energy is $\hbar\omega = \frac{\hbar k^2}{2m}$ and the average momentum is $|\langle s' | p_i | s \rangle|^2 = \frac{\hbar^2 k^2}{4}$. In such a case $f_{s, s'} = N$ the total number of free charge carriers. After performing the integral in Eq. 44 the final result for the leading order conductivity calculated *via* the Kubo formalism is

$$\sigma_1^{Kubo}(\omega) = \frac{Ne^2\tau}{m} \frac{1}{1 - i\omega\tau}, \quad (45)$$

which is the exact same result as calculated classically *via* the Drude model above. For more details see the chapters in Wooten (?) and Mahan (3).

III. TECHNIQUES

As mentioned above, the incredibly large spectral range spanned by the typical energy scales of solids means that many different techniques must be used. Below I discuss the most used techniques of microwave measurements, THz spectroscopies, optical reflectivity, and ellipsometry that are used to span almost six orders of magnitude in measurement frequency. These various regimes are loosely defined below, but of course there are overlaps between them⁶.

A. Microwaves

Until recently measurements in the microwave range (100 MHz - 100 GHz) were performed almost entirely

using microwave cavity resonator techniques.⁷ In microwave cavity resonance techniques, one is less sensitive to such considerations as the sample forms part of a resonance circuit, which dominates the measurement configuration. Typically one measures transmission through a cavity, which is only possible when at resonance. The technique is widely used for the study of dielectric and magnetic properties of materials in the GHz range, because of its high sensitivity and relative simplicity.

A microwave resonator is typically an enclosed hollow space of cylindrical or rectangular shape machined from high-conductivity metal (typically copper or superconducting metals) with interior dimensions comparable to the free-space wavelength. On resonance, an electromagnetic standing wave pattern is set up inside the cavity. One characterizes the resonance characteristics of the cavity, both with and without a sample inside. Upon sample introduction the resonance’s center frequency shifts and it broadens. From the shifting and broadening, one can define a complex frequency shift, which with knowledge of the sample size and shape allows one to quantify the complex conductivity directly. For instance, in the limit of very thin films, the center frequency shift is proportional to σ_2 and the broadening is proportional to σ_1 . For samples much thicker than the skin or penetration depth, different relations apply (25). The fact that the measurements are performed “on resonance” means that a very high sensitivity is achieved. The technique does have the considerable disadvantage that only discrete frequencies can be accessed, as one is limited to the standing wave resonance frequencies of the cavity, which means that true spectroscopy is not possible. In such measurements one typically determines a sample’s complex conductivity as a function of temperature at some finite fixed frequency (See Figs. 32, 33 and 34).

In contrast, the Corbino geometry is a measurement configuration that is capable of *broadband* microwave spectroscopy. It is compatible with low T and high field cryogenic environments and capable of broadband microwave spectroscopy measurements from 10 MHz to 40 GHz. It is a relatively new technique, but one which has recently been used with great success by a number of groups in the correlated electron physics community (26; 27; 28; 29; 30; 31). Although powerful, it has the disadvantage that its use is confined to samples which have typical 2D resistance within a few orders of magnitude of 50 Ohms.

⁶ Although I don’t discuss them, one might naturally include various radio frequency techniques in this list (which would increase the frequency range by another three orders of magnitude at least at the low end). At typical experimental temperatures, the low frequency available in techniques like mutual inductance measurements allows almost the DC limit of quantities like the superfluid density in superconductors to be measured. Interested readers are directed to Ref. (24) and reference therein.

⁷ At lower frequencies (kHz and MHz), measurements can be performed by attaching contacts to samples and the complex conductivity can be measured by lock-in techniques, network analyzers, and impedance analyzers. Such methods become problematic in the GHz range however, as wavelengths become comparable to various measurement dimensions (sample size, microwave connector dimensions, cable lengths), and capacitive and inductive effects become appreciable.

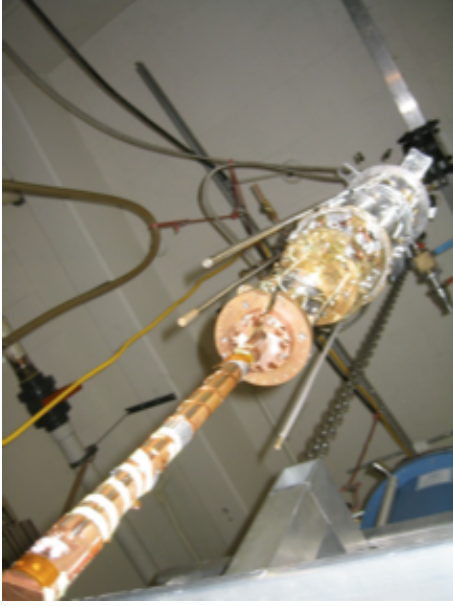


FIG. 7 (Color) View of the UCLA He3 ‘CryoMag’ system. Cavities can be interchanged quickly to enable a number of different frequencies to be accessed.

In a Corbino geometry spectrometer a microwave signal from a network analyzer is fed into a coaxial transmission line. A schematic is shown in Fig. 8 (left). The signal propagates down the coaxial line and is reflected from a sample that terminates an open ended coaxial connector. The network analyzer determines the complex reflection coefficient S_{11} of the sample which can be related to the complex sample impedance Z_L via the relation $S_{11} = \frac{Z_L - Z_0}{Z_L + Z_0}$ where Z_0 is the coaxial line impedance (nominally 50Ω). Because the sample geometry is well defined, knowledge of the sample impedance yields intrinsic quantities like the complex conductivity. In the typical case of a thin film where the skin or penetration depth is much larger than the sample thickness d , the sample impedance is related in a straightforward fashion to the complex conductivity as $\sigma = \frac{\ln(r_2/r_1)}{2\pi d Z_L}$ where r_1 and r_2 are the inner and outer conductor radii respectively.

An experimental challenge in Corbino geometry measurements is that the coaxial cables and other parts of the transmission lines can have strongly temperature dependent transmission characteristics. Errors in the intrinsic reflection coefficient, coming from standing wave reflections or phase shifts and damping in the transmission lines, are accounted for by performing a number of calibration measurements. It is imperative that the same cryogenics conditions are reproduced between calibration and each subsequent measurement. In general this is easily done by ensuring the same starting conditions and using a computer controlled cool-down cycle. Recently it has been demonstrated that a three sample calibration (open, short, and a standard 50 ohm resistor) at all

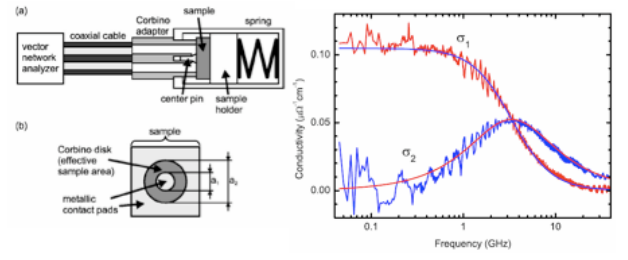


FIG. 8 (Color) (left) Experimental geometry for a Corbino spectrometer. (right) The real and imaginary parts $\sigma_1 + i\sigma_2$ of the optical conductivity spectrum of UPd_2Al_3 at temperature $T = 2.75 \text{ K}$. The data are fit to $\sigma_{dc}(1 - i\omega\tau)^{-1}$ with $\sigma_{dc} = 1.05 \times 10^5 (\Omega - \text{cm})^{-1}$ and $\tau = 4.8 \times 10^{-11} \text{ s}$ and show excellent agreement with the Drude prediction. Adapted from Refs (26; 27)

temperatures dramatically increases the precision of the technique over previous single sample calibrations (26).

As an example of the power of the technique we show in Fig. 8 (right) recent measurements taken on films of the heavy-fermion compound UPd_2Al_3 at $T = 2.75 \text{ K}$. The data show almost ideal Drude behavior with a real conductivity of Lorentzian shape and an imaginary conductivity that peaks at the same ω as the real conductivity has decreased by half. The anomalous aspect is the Drude peak is seen to be of remarkably narrow width - almost 500 times narrower than that of a good metal like copper. This is a consequence of the mass renormalizations in the heavy fermion compounds and a feature that would have been completely undetectable with a conventional spectrometer.

Recently there also been the very interesting development of a bolometric technique for high-resolution broadband microwave measurements of ultra-low-loss samples, like superconductors and good metals (32). This technique is a non-resonant one where the sample itself is actually used as a detector in a bolometric fashion. Microwaves are fed through a rectangular coaxial transmission line into which the sample under test and a reference sample are mounted. Small changes in the sample and reference’s temperature are monitored as they absorb microwave radiation. The key to the success of this technique is the *in situ* use of this normal metal reference sample which calibrates the absolute microwave incident power. As the absorbed power is proportional to the surface resistance $R_s(\omega)$, the independent measure of the incident power allows one to measure the surface resistance precisely.

In such an apparatus, the sample temperature can be controlled independently of the 1.2 K liquid-helium bath, allowing for measurements of the temperature evolution of the absorption. The minimum detectable power of this method at 1.3 K is 1.5 pW , which corresponds to a surface impedance sensitivity of $\approx 1 \mu\Omega$ for a typical $1 \text{ mm} \times 1 \text{ mm}$ platelet sample. The technique allows very

sensitive measurements of the microwave surface resistance over a continuous frequency range on highly conducting samples. This is a region of sample impedances generally inaccessible with the Corbino technique and only available at discrete frequencies in microwave cavities.

A disadvantage of the technique is that although one measures $R_s(\omega)$ the quantity of interest is typically the complex conductivity $\sigma(\omega)$. One must make various assumptions to get this from the relation for surface impedance

$$Z_s = R_s + iX_s = \sqrt{\frac{i\omega\mu_0}{\sigma_1 + i\sigma_2}}. \quad (46)$$

as the surface reactance X_s is not measured. At low temperatures and frequencies in the superconducting state σ_2 is mostly determined by the superconducting response and can be related to the independently measured penetration depth λ . σ_1 then follows from the relation $R_s = \frac{1}{2}\mu_0^2\omega^2\lambda^3\sigma_1$. At higher temperatures and frequencies a more complicated iterative procedure must be used that is based on the Kramers-Kronig transform (32).

This technique has been used to measure the real part of the conductivity of $\text{YBa}_2\text{Cu}_3\text{O}_{6.5}$ single crystals across a wide frequency range as shown in Fig. 9. One can see a quasi-Drude like peak at low frequencies that comes from quasi-particle excitation at the nodes of the d -wave superconductor. The peak has a narrow width of the order of 5 GHz, signifying a collapse of quasiparticle scattering in the superconducting state and very long quasiparticle scattering lengths. This is indicative of the very high quality of these $\text{YBa}_2\text{Cu}_3\text{O}_{6.5}$ single crystals. Measurements of a broadband nature on these kind of materials are not possible with other techniques. As powerful as it is, the technique is hampered by the fact that various assumption must be made about σ_2 . This is problematic for materials where its dependence is not known *a priori*.

In addition to the ones detailed above, there are many other techniques which have been used for materials characterization in the microwave range. These include microstrip and stripline resonators, transmission line wave bridges, radio frequency bridges, parallel-plate resonators, and helical resonators, See Ref. (2; 33; 112) for further details.

B. THz spectroscopy

Time scales in the picosecond (10^{-12} sec) range are among the most ubiquitous in condensed matter systems. For example, the resonant period of electrons in semiconductors and their nanostructures, the scattering times of electrons in metals, vibrational frequencies of molecular crystals, superconducting gap energies, the lifetime of biologically important collective vibrations of proteins, and - now - even the transit time for an electron in Intel's new THz transistor - these are all picosecond phenomena. This ubiquity means that experimental probes em-

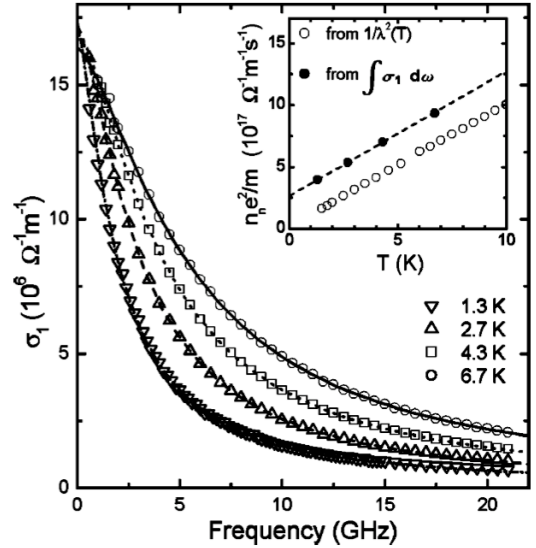


FIG. 9 The real part of the microwave conductivity $\sigma_1(\omega)$ extracted from measurements of $R_s(\omega)$ as described in the text and Ref. (32). Figure adapted from (32).

ploying Terahertz (THz) electromagnetic radiation are potentially quite powerful. It is unfortunate then that this spectral range lies in the so-called ‘Terahertz Gap’ - above the capabilities of traditional electronics and the microwave range, but below that of typical optical instrumentation. The THz spectral region has been a traditionally difficult part of the electromagnetic spectrum to work in because of a number of reasons including weak sources, long wavelengths, and contamination by ambient room temperature black body radiation. In recent years, however, there have been a number of developments that allow measurements in the THz range in a manner that was not previously possible. These come in the form of time domain THz spectroscopy and the increasing prevalence of Backward Wave Oscillator (BWO) based spectrometers. In recent years, however, a number of dramatic technical advances such as *time-domain* THz spectroscopy (TDS) using so-called ‘Auston’ switch generators and detectors have enabled measurements that span this gap in measurement possibilities.

THz spectroscopy has become a tremendous growth field (34), finding use in a multitude of areas including characterization for novel solid-state materials (35; 36), optimization of the electromagnetic response of new coatings (37), probes of superconductor properties (38; 39), security applications for explosives and biohazard detection (40), detection of protein conformational changes (41), and non-invasive structural and medical imaging (42; 43; 44).

TDS works (See Ref. (45) for an additional excellent short summary) by the excitation of a source and activation of a detector by ultrafast femtosecond laser (typically Ti-sapphire) pulses. A basic schematic is shown in Fig. 10. A femtosecond laser has, *via* a beam split-

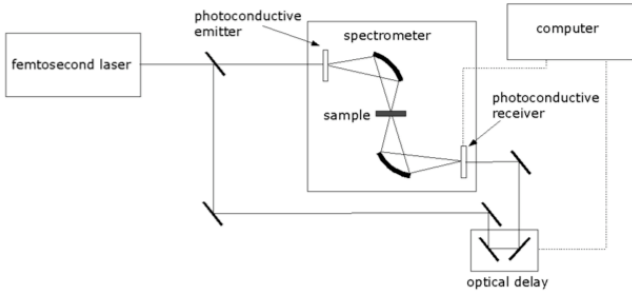


FIG. 10 A diagram of a typical experimental layout used in TDFS.

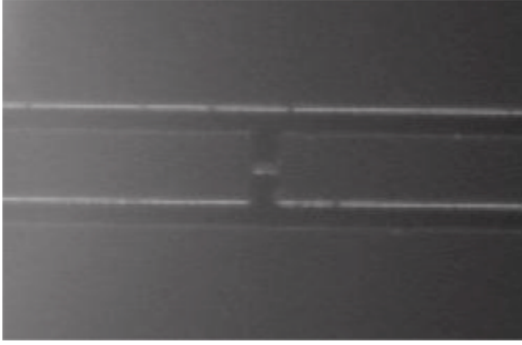


FIG. 11 An optical image of the two-contact photoconductive 'Auston' switch antenna structure used in TDFS. Two electrodes are grown on top of an insulating high defect semiconductor, like low temperature grown GaAs or radiation damaged silicon. Electrode spacing is typically on the order of 10 microns.

ter, its radiation split off to fall on source and detector Auston switches, which are typically pieces of low temperature-GaAs or radiation damaged silicon with two electrodes grown on top in a dipole arrangement and separated by approximately $20 \mu\text{m}$ (Fig. 11). Before laser illumination, the switch has a resistance of a few megaohms. After the fast illumination by the femtosecond laser pulse, the source switch's resistance falls to a few hundred ohms and with a bias by a few tens of volts, charge carriers are accelerated across the gap on a time scale of a few picoseconds. Their acceleration produces a pulse of almost single-cycle radiation, which then propagates through free space and - collimated by mirrors and lenses - interacts with the sample. Measurements have been typically performed in transmission. After passing through the sample, THz radiation falls on the second Auston switch, which is also activated by the femtosecond pulse. Whereas the first Auston switch was DC biased, the 2nd Auston switch is biased by the electric field of the THz radiation falling upon it. Current can flow only across the second switch with a direction and magnitude proportional to the transient electric field at the instant the short femtosecond pulse impinges on it. The experimental signal is proportional to this current with

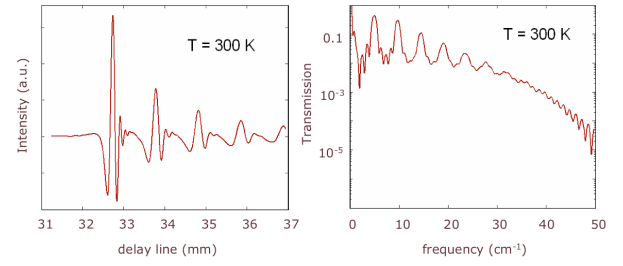


FIG. 12 (Color) (left) Time-domain trace of electric field transmission through $60 \mu\text{m}$ thick SrTiO_3 substrate. Multiple reflections from front and back surfaces are readily visible. (right) Power spectrum of the transmission through the same $60 \mu\text{m}$ thick SrTiO_3 substrate. The data is obtained from the squared Fourier transform of the data in (left) and ratioed to a reference aperture signal. From Ref. (46)

a magnitude and polarity that reflects the THz electric field at the switch. A delay line is then advanced and the THz electric field at a different relative times can be measured. In this way, the entire electric field profile as a function of time can be mapped out as shown in Fig. 12(left). The time-domain pulse is then Fourier transformed to get the complex electric field as a function of frequency. A reference measurement is also performed on an aperture with no sample. The measured transmission function is the ratio of the signal transmission to the reference [Fig. 12(right)].

There are a number of unique aspects to TDFS that allow it to work exceptionally. Since the detected signal is proportional to the instantaneous electric field, and not the power, the measured transmission function is the *complex* transmission coefficient for the *electric field*, which has both an amplitude and a phase. This allows one to invert the data directly to get the real and imaginary optical constants (e.g. the complex conductivity) of the material. This is essential for a thorough characterization of material's properties. Typical optical measurements discussed below measure only reflected or transmitted power, quantities in which the complex optical constants of interest are confolded into in a non trivial fashion. In such measurements one has to measure over the largest frequency range possible (even if one is only interested in a limited spectral range), extrapolate to both DC and infinite frequency, and then Kramers-Kronig transform to get phase information. In TDFS one can get both components by direct inversion.

TDFS is also capable of unprecedentedly high signal-to-noise ratios. Typically efforts in the THz and far infrared spectral range are complicated by a very large ambient black body radiation background. In the case of TDFS the fact that the signal is 'time-gated' and coherent, whereas black-body radiation is incoherent, allows a very high detection efficiency. Additionally, since the detected quantity is actually electric field and not power (proportional to electric field squared), the noise in the spectral power is reduced by a factor proportional

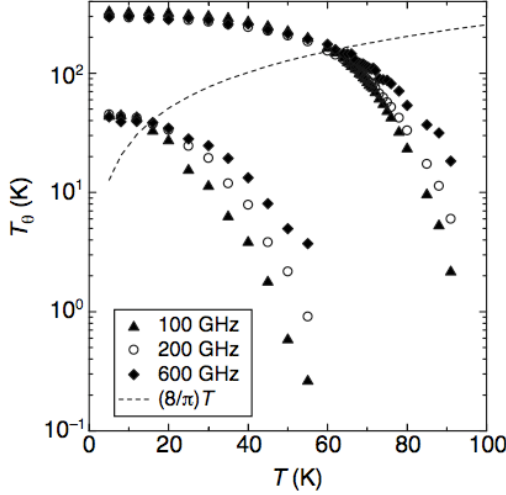


FIG. 13 The dynamic (frequency dependent) phase stiffness $T_\theta(\omega)$ as a function of temperature T . Data are shown for two samples, one with T_c 33 K. The data for each sample correspond to measurement frequencies of 100, 200 and 600 GHz. Each set of curves identify a crossover from frequency-independent to frequency-dependent phase stiffness. The dashed line shows that the crossover is set by the Kosterlitz-Thouless-Berezinskii condition for two-dimensional melting. From Ref. (39)

to the electric field itself. These aspects allow detection of transmission signals approaching one part in 10^6 . This is an incredibly large dynamic range and is essentially unprecedented in optically based spectroscopies where one part in 10^3 is typically considered extremely good.

TDTS was used for instance in the measurement of thin Bi2212 cuprate superconducting films to show evidence for phase fluctuations above T_c . Corson *et al.* measured transmission through thin films and using the unique phase sensitivity of TDTS could show that there was an enhanced σ_2 (Fig. 13) even at temperatures well above T_c (39). This was interpreted as a finite phase stiffness on short length and time scales. Superconducting fluctuations as such should manifest themselves as a finite superfluid stiffness measured at finite frequency. The imaginary part of the optical conductivity is sensitive to superfluid stiffness through the relation $\sigma_2 = \sigma_Q \frac{k_B T_\theta}{\hbar \omega}$, where $\sigma_Q = \frac{4e^2}{\hbar d}$ is the quantum of conductance for Cooper pairs divided by a length scale (typically the c-axis lattice constant) and T_θ is the generalized frequency dependent superfluid stiffness. Here, the superfluid stiffness T_θ is an energy scale expressed in temperature units. The stiffness is the energy scale to introduce phase twists in the superfluid order parameter $\Psi = \Delta e^{i\phi}$.

The other major development for THz spectroscopy is the increased prominence of Backward Wave Oscillators (BWOs) Although developed in the 60's, BWOs are gaining increasing prominence in the investigation of correlated systems in the important THz range (47). These BWOs are traveling wave guide tubes, capable of pro-

ducing very monochromatic THz range radiation over a relatively broad range per device. With a number of tubes, it is powerful method to cover the 0.03 THz to 1.5 THz range in a continuous wave configuration.

The longer wavelengths in this spectral region give the capabilities to measure phase of transmitted waveforms through Mach-Zender two-beam polarization interferometry. This method also allows direct precision measurements of both real and imaginary components of the complex optical response without resort to Kramers-Kronig transforms and their associated ambiguities. A spectrometer based on BWOs is easily integrated with a low temperature cryostat and magnetic field system as well as glove boxes for environmental control.

C. Infrared

Fourier transform infrared reflectivity (FTIR) is the workhorse spectroscopy for optical characterization of solids (Fig. 15). Measurements are possible from $\sim 10 \text{ cm}^{-1}$ to approximately $25,000 \text{ cm}^{-1}$, although measurement get increasingly difficult below 50 cm^{-1} . Heroic efforts can push the lower end of this range slightly below 10 cm^{-1} (48). Here the quantity of interest is typically the power reflectivity (transmission measurements are possible as well). One shines broadband light, sometimes from several different sources, on a sample surface and *via* an interference technique measures the reflected intensity. As the source spectrum and detector response can have all kinds of frequency structure, it is necessary to reference the reflected signal against a standard sample to obtain the absolute reflectivity. Typically the reference spectrum is chosen to be a noble metal like gold whose reflectance can to good approximation be taken to be unity over a broad frequency region below the material's plasma frequency (see below). Typically gold is evaporated onto a sample as shown in Fig. 14 or the sample is replaced with a mirror to perform this referencing.

As the materials we are interested in typically have interesting experimental signatures in both the real and imaginary response, it is not sufficient to compare to theory by simply measuring quantities like *absorbance*. We want quantities like the complex conductivity or dielectric function. It is not necessarily straightforward to obtain a complex quantity from the measured scalar magnitude of the reflectivity $R(\omega)$. Unlike TDTS, phase is not measured in FTIR measurements. Therefore typically use is made of the above discussed Kramers-Kronig transforms, which apply to any causal response function. If one knows one component of the response (real or imaginary) for all frequencies then one can determine the other component. For reflected power, one can obtain the reflected phase as

$$\phi(\omega) = -\frac{1}{\pi} P \int_{-\infty}^{\infty} d\omega' \frac{\ln|R(\omega')|}{\omega' - \omega}. \quad (47)$$

Reflectivity (Far-IR – Near-IR)

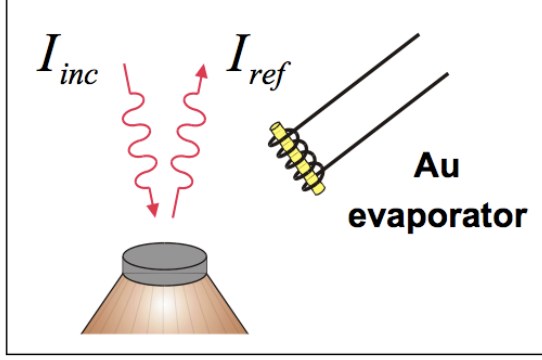


FIG. 14 (Color) Absolute reflectivity $R(\omega)$ in FTIR is obtained by measuring the reflected intensity and ratioing with the intensity after gold evaporation or from a reference mirror. Figure courtesy of A. Kuzmenko.

Of course the problem is that one doesn't measure over an infinite frequency range. In typical FTIR spectroscopy, the usual mode of operation is therefore to measure over as large a frequency range as possible and then extrapolate with various schemes to $\omega \rightarrow 0$ and $\omega \rightarrow \infty$. This method works quite well for some materials, although it can generate large errors when, for instance, reflectivities approach unity as they do in good conductors at low frequencies. It can also be rather inefficient and cumbersome as one must measure out to the multi-eV range even if one is interested in meV level phenomena.

As mentioned, FTIR spectroscopy is a standard spectroscopic technique for the characterization of materials and chemicals. It is used routinely to identify the presence of various chemical bonds in chemistry as in, for instance, $C = C$ or $C = O$, which all have distinct frequencies and absorptive strengths. It is also the standard optical tool for probing materials like high- T_c superconductors (9). It has the advantage of being relatively easy to perform and possessing a very large spectra range. It has the above mentioned disadvantage of only measuring a scalar - the power - and having a lower bound on the spectral range that is at the limit of that explicitly relevant for many correlated materials.

D. Visible and Ultraviolet

The technique of optical reflection as outlined above begins to become more difficult at frequencies on the order of the plasma frequencies of metals. To do reflectivity measurements, one always needs a standard sample. Standard metal references cannot be used above their plasma frequencies as their reflectivity changes quickly with frequency. Quartz or silicon which have an approximately flat (but low) reflectivity can be used as a reference in a *grating spectrometer* (49). However, more common nowadays is to use techniques such as ellipsome-

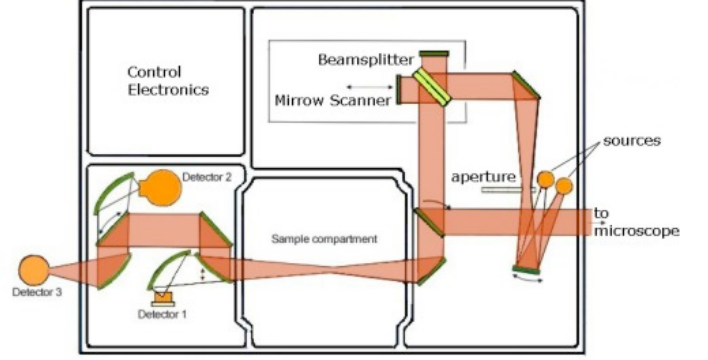


FIG. 15 (Color) Modified Fourier Transform Spectrometer Bruker 66. As shown, the spectrometer is setup to perform reflection, but with additional mirrors near-normal incidence reflection is possible. The apparatus works by shining broad band light from a variety of sources on a sample. Reflected or transmitted intensity is measured with a few different detectors. A beamsplitter/interferometer apparatus allows the resolution of distinct frequency components. Figure from <http://www.pi1.physik.uni-stuttgart.de/research/Methoden/FTIR.e.php>. Figure courtesy of N. Drichko.

try to determine complex optical coefficients in this spectral range as one can measure complex response functions directly.

Ellipsometry is an optical technique for determining properties of surfaces and thin films. Although the method was originally used as far back as 1887 by Paul Drude to determine the dielectric function of various metals and dielectrics, it only gained regular use as a characterization tool in the 1970s (50; 51). It is now widely used in the near infrared (NIR) through ultraviolet (UV) frequency ranges in semiconductor processing for dielectric and thickness characterization.

When linearly polarized light is reflected from a surface at glancing incidence the in- (p) and out-of-plane (s) of incidence light is reflected at different intensities as well as suffering a relative phase shift. The reflected light becomes elliptically polarized as shown in Fig. 16. The shape and orientation of the ellipse depend on the angle of incidence, the initial polarization direction, and of course the reflection properties of the surface. An ellipsometer measures the change in the light's polarization state and characterizes the *complex* ratio ρ of the in- (r_p) and out-of-plane (r_s) of incidence reflectivities. The Fresnel equations allow this quantity to be directly related to various intrinsic material parameters, such as complex dielectric constant or layer thicknesses.

The ellipsometer itself is designed to measure the change in polarization state of the light reflected from a surface at glancing incidence. From a knowledge of the orientation and polarization direction of the incident light one can calculate the relative phase difference, Δ ,

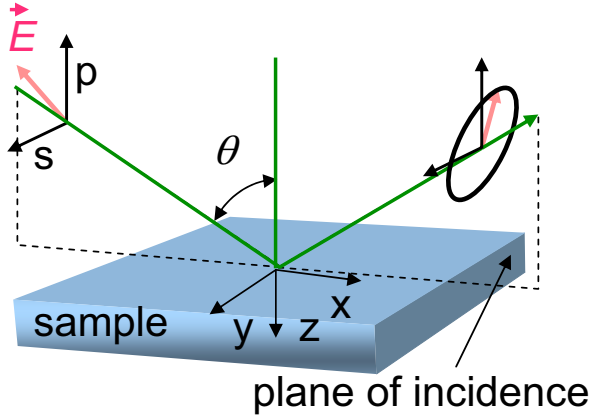


FIG. 16 (Color) Schematic showing the basic principle of ellipsometry. Glancing incidence light linearly polarized with both s and p components is reflected with different intensities and a relative phase shift. A characterization of the resulting elliptically polarized reflected light's minor and major axes, as well as tilt angle gives a unique contribution of the complex optical constants of the material.

and the relative amplitude difference ($\tan\Psi$) between the two polarization components that are introduced by reflection from the surface.

Given the *complex* ratio $\rho = r_p/r_s = e^{i\Delta}\tan\Psi$ of the in- (r_p) and out-of-plane reflectivities (r_s), various intrinsic material parameters can be generated *via* the Fresnel equations. In a homogeneous sample the complex dielectric constant $\epsilon = \epsilon_1 + i\epsilon_2$ is related to ρ as given in Eqs. 48, 49 and 50 below. Here as usual ϵ_1 parameterizes the polarizability of a material, whereas ϵ_2 parameterizes the dissipative properties. ϵ_z is the complex dielectric constant perpendicular to the reflection surface and ϵ_x is the complex dielectric constant in the plane of the reflection surface, and θ is the angle of incidence as shown in Fig. 16.

$$\rho = r_p/r_s = \tan\Psi e^{i\Delta}, \quad (48)$$

$$r_p = \frac{\sqrt{1 - \epsilon_z^{-1}\sin^2\theta} - \sqrt{\epsilon_x}\cos\theta}{\sqrt{1 - \epsilon_z^{-1}\sin^2\theta} + \sqrt{\epsilon_x}\cos\theta}, \quad (49)$$

$$r_s = \frac{\cos\theta - \sqrt{\epsilon_y - \sin^2\theta}}{\cos\theta + \sqrt{\epsilon_y - \sin^2\theta}}. \quad (50)$$

In a typical configuration, monochromatic light is incident on a glancing trajectory θ close to the Brewster angle (usually $\sim 65 - 85^\circ$ for bad metals at high frequencies) with a linear polarization state of 45° . As the typical detector measures power and not electric field, it is essential that the light's elliptical polarization is measured over at least 180° (and more typically 360°). To completely characterize the phase, it is clearly *not* sufficient to simply measure the projection of the ellipse along

two orthogonal directions, as can be seen by construction in Fig. 17. In order to get the phase information, the ellipse's orientation and major and minor axes must be known. Generically, the light originally linearly polarized at 45° is changed to an elliptical polarization with its major axis displaced from 45° . A characterization of this ellipse's major and minor axes, as well as tilt angle is a direct measure of the complex amplitude reflection coefficients, which can then be related to intrinsic material quantities.

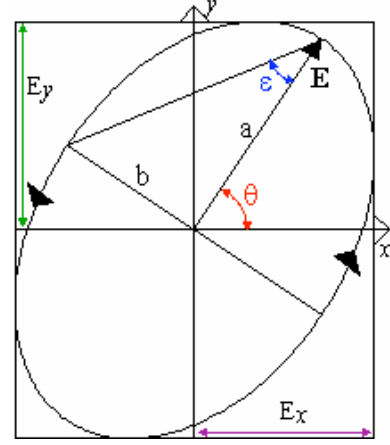


FIG. 17 (Color) To completely characterize the electric field vectors and their phase, it is insufficient to measure the projection of the ellipse along two orthogonal directions. The complete ellipse must be mapped out to get its major and minor axes and tilt angle.

The fact that ellipsometry measures the ratio of two simultaneously measured values gives it several distinct advantages as a characterization tool over simple reflectivity. It is highly accurate and reproducible even at low intensities as many systematic errors are divided out. Moreover, unlike reflectivity measurements, the technique is self-normalizing and a reference sample is not necessary. This is important as the choice of a reference can be problematic in the optical and ultraviolet spectral range or when the surface is of unknown quality. The method is also particularly insusceptible to source intensity fluctuations as they are also divided out. Perhaps most important for the overall utility of the technique is that the method also measures a phase, which gives additional information regarding materials properties. The phase information can be used to generate the *complex* optical constants (the complex dielectric constant for instance, or the complex index of refraction n and k or the complex conductivity σ) which is essential information for a complete characterization of a material's optical response. If the optical constants are known, the phase information can be used to sensitively measure films thicknesses. If conventional ellipsometry has a disadvantage it is that with typical grating monochromator data acquisition (i.e. one frequency stepped at a time) it is relatively slow as both the grating and polarizers must

continue to be moved. In such a setup one loses the rapid acquisition time of the multiple frequency multiplexing in, for instance, Fourier transform infrared reflectivity (FTIR)⁸. As mentioned above, the technique is well established and widely used in the NIR through ultraviolet (UV) frequency ranges (52; 53). There have been a number of attempts to extend ellipsometry to lower infrared frequencies (52; 53; 54). Unfortunately the lack of sufficiently intense sources (among other reasons) has meant that such efforts have met with limited success, although synchrotron based efforts have had some success in this regard (55).

The energy scales of the visible and ultraviolet, which are measured by ellipsometry are not usually explicitly relevant for strongly correlated systems. Typically we are interested in much lower energies that are on the order of the temperatures that phenomena are exhibited. However, such energies are relevant for the determination of important band structure parameters on, say, 3D materials that photoemission cannot be performed on. Excitations in this range also determine the high frequency dielectric constant ϵ_∞ , which can have a significant (but indirect) effect of the low energy physics. Characterization of optical constants in the visible and UV range is also imperative to constrain the phase information at low energies when performing Kramers-Kronig with reflectivity data. Recently an extremely powerful method for combining different data sets using a Kramers-Kronig consistent variational fitting procedure was developed by A. Kuzmenko (56). It allows a general procedure for combining say, DC resistance, cavity microwave measurements at a few distinct frequencies, IR power reflectivity, and ellipsometry to extract over a broad energy range of all the significant frequency and temperature dependent optical properties.

IV. EXAMPLES

A. Simple Metals

Noble metals like silver, copper, and gold provide a good first step for the understanding the electrodynamics of solids. Compare the reflection spectra of silver and gold (and aluminum) given in Fig. 18 as a function of energy. The reflection spectra of silver shows a sharp plasma edge around 3.8 eV. Gold has a much lower plasma frequency with its plasma edge at a wavelength of around 2.5 eV. Also shown is the reflection spectra for aluminum which has a much larger plasma frequency than any of these at around 15.5 eV. The small dip in Al around 1.65 eV is caused by an interband absorption (see below) and is not its plasma frequency.

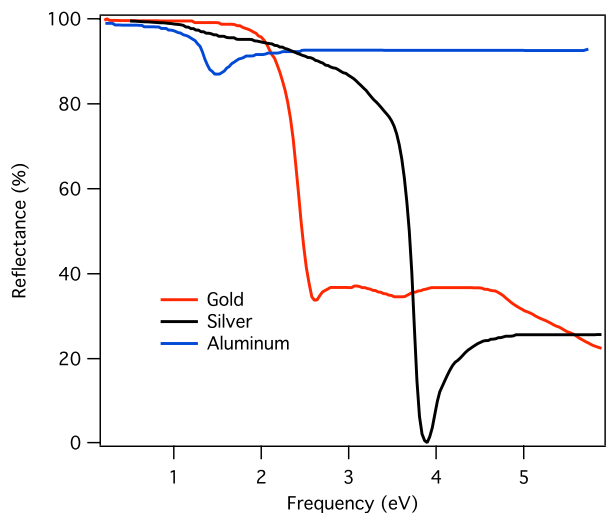


FIG. 18 (Color) Reflectance curves for aluminium (Al), silver (Ag), and gold (Au) metal at normal incidence as a function of incident energy. The plasma frequencies of silver and gold are clearly seen. The small dip in aluminum's curve around 1.65 eV is caused by an interband absorption and is not its plasma frequency. Aluminum's plasma frequency lies at much higher energies at around 15.5 eV. Adapted from Ref. (57).

From these spectra we can immediately see the origin for the visual difference between silver and gold. As mentioned above, the reflection/transmission properties of metals greatly change above their plasma frequencies. If not for the presence of interband transitions, metals would be transparent in this regime. The lower plasma frequency of gold is what determines its yellowish color in reflection. It reflects less in the blue/violet portion of the spectra and hence looks yellowish. In contrast the plasma frequency of silver is in the UV range and so the reflection of silver is almost constant at constant throughout the infrared to visible range. Aluminum's plasma frequency is higher yet still and so the major differences in its optical properties as compared to silver are invisible to the human eye.

As discussed above, within the Drude model with only free carriers the plasma frequency is set by $\omega_p = \sqrt{\frac{4\pi N e^2}{m}}$. This is frequency of the dip in the reflectivity, the zero crossing in ϵ_1 , and the frequency of free longitudinal charge oscillations (the *plasmon* frequency). However, the presence of interband excitations, which contribute a high frequency dielectric constant ϵ_∞ changes the situation. In real materials, these features are exhibited at the so-called *screened* plasma frequency set by $\tilde{\omega}_p = \sqrt{\frac{4\pi N e^2}{\epsilon_\infty m}}$. It is interesting to note that the carrier density and masses of silver and gold are almost identical and so the difference in their plasma frequencies comes almost entirely from the renormalization effects of different interband transitions ϵ_∞ .

Data like that shown in Fig. 18 can, with appropriate

⁸ In FIR ellipsometers one typically uses the interferometer of an FTIR spectrometer, which retains this multiplexing.

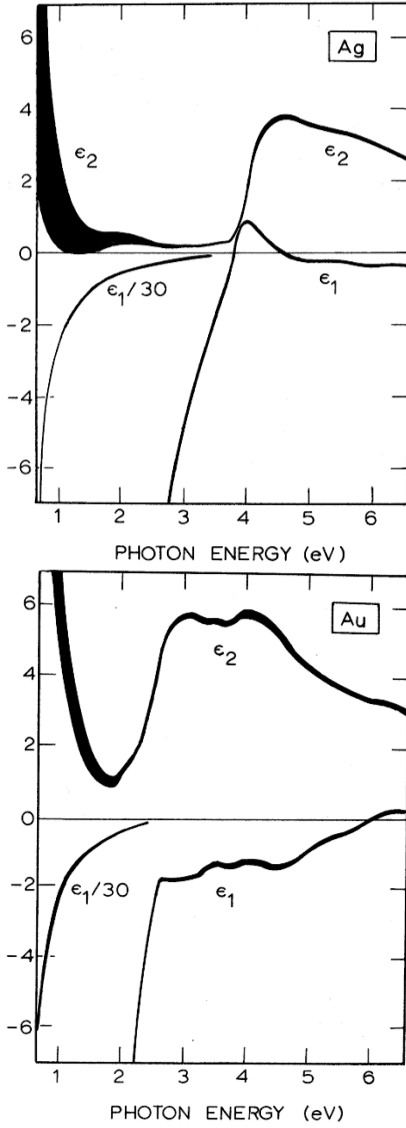


FIG. 19 Real and imaginary dielectric functions for silver (top) and gold (bottom). The thickness of the curve indicates the experimental uncertainty, which originates mainly in the Kramers-Kronig transform. From Ref. (58).

extrapolations to high and low frequency, be Kramers-Kronig transformed to get the real and imaginary dielectric function as shown in Fig. 19 for silver and gold. As expected they both show strong almost perfect $\omega = 0$ Lorentzian Drude peaks of almost equal weight, but gold shows stronger interband absorptions, gives it a larger ϵ_∞ that renormalizes its plasma frequency⁹. Such spectra can be decomposed into various contributions as shown

⁹ Recall from section V.B that a low frequency oscillator (absorption) can give a large ϵ_∞ . All other things being equal, the lower the frequency of the oscillator the higher the ϵ_∞ .

in Fig. 20 for silver. As expected there is a strong zero frequency Drude peak contribution as well as interband contributions. Although the interband piece shows some resemblance to the Drude-Lorentz plots in Fig. 6, the shape is a more rounded cusp, which is characteristic of transitions within the manifold of d-electron states.

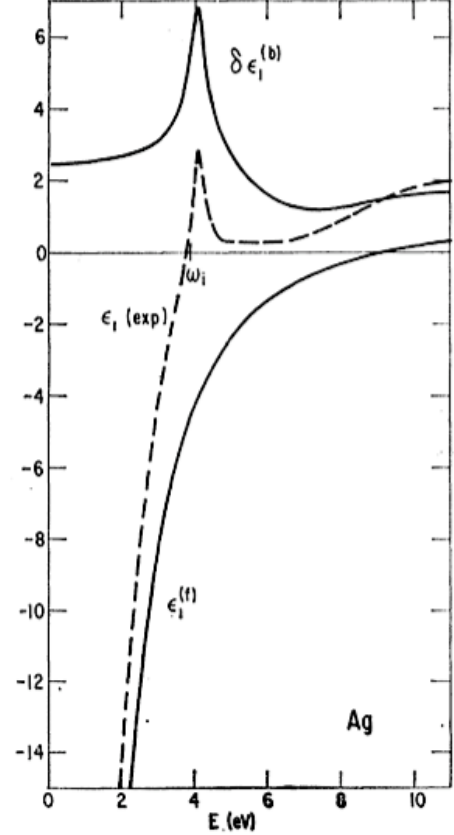


FIG. 20 Decomposition of the dielectric function of silver into Drude and interband contributions. The threshold absorption for interband excitations is indicated by ω_i . $\epsilon_1^{(d)}$ is the Drude contribution. $\delta\epsilon_1$ is the interband piece. From Ref. (60).

In Fig. 21 a similar plot of the complex response functions for aluminum is shown. In addition to the metallic $\omega = 0$ Lorentzian Drude peak, the prominent absorption that gives the dip in the reflectivity curve around 1.65 eV can be clearly seen. That this dip in the reflectivity does not reflect the plasma frequency can be seen in the plot of the loss function $\text{Im}(-\frac{1}{\epsilon})$, which shows a strong peak only at the 'screened' plasma frequency 15.5 eV (i.e. the zero cross of ϵ_1).

B. Semiconductors and Band Insulators

In semiconductors and band insulators, the real part of the conductivity is dominated by interband transitions (red in Fig. 2). At low temperatures in a clean undoped insulator, naively one expects to see a gap with no conductivity and then a sudden onset at the gap edge. In

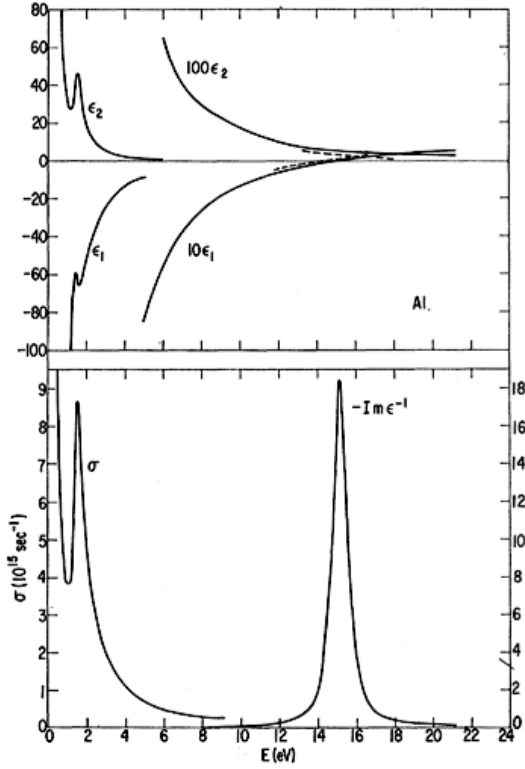


FIG. 21 (top) Real and imaginary dielectric functions for aluminum. (bottom) Real part of the conductivity and the loss function. In addition to the Drude peak, a prominent absorption is found around 1.65. This feature gives the dip in the reflectivity curve around the same energy. The loss function shows a strong peak at the screened plasma frequency 15.5 eV. From Ref. (59).

fact, various other contributions are also possible inside the gap. Electron-hole pair bound states can form as excitons and give dissipative response and be seen as sharp peaks below the gap. This is found for instance in Fig. 22 for the ionic insulator KCl, where in addition to the band edge excitation there are a series of below gap exciton absorptions. Even lower measurement frequencies than those shown would reveal a series of sharp peaks from optical phonons down in the 50 meV range. Such behavior can be seen in Fig. 23 for MgO and FeSi.

If one starts to dope into a typical semiconductor like phosphorus into silicon, massive changes in the optical spectra occur. At very low doping levels one can discern the sharp absorptions of individual donors as seen in the bottom of Fig. 24. As the dopant density is increased inter-pair and inter-cluster quantum tunneling broadens the spectra until a prominent impurity band forms in the gap as shown in Fig. 25. Charge transitions can occur in this manifold of impurity states. Below a certain critical doping such a doped state retains its insulating character and is termed an *electronic glass*. I discuss this state of matter below.

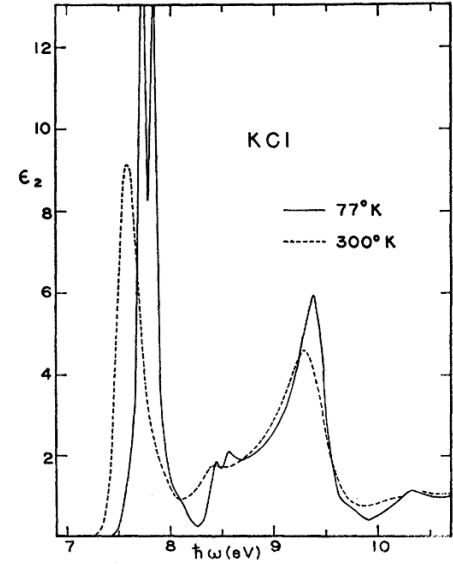


FIG. 22 Imaginary dielectric function of KCl. The absorption around 9 eV is the band gap. The series of sharp features at energies below the band gap are due to excitons. From Ref. (61)

C. Electron glasses

Many crystalline and amorphous semiconductors show a metal-insulator transition (MIT) as a function of dopant concentration or stoichiometry. On the insulating side of the transition, the materials are insulators not principally for the reason of completely filled bands (as in the case of a band insulator) or interactions (as in the case of a Mott insulator), but because electronic states at the chemical potential are localized due to disorder. Such materials which have a random spatial distribution of localized charges have been called - in analogy with structural glasses - *electron-glasses* and are more generally termed Anderson insulators.

At finite temperatures these materials conduct under DC bias *via* thermally activated transport of charges hopping between localized states in an impurity band. Hence, the DC conductivity tends to zero as the temperature tends to zero. However, because their insulating nature derives from localization of the electronic orbitals and not necessarily a vanishing density of states at E_F , such materials can have appreciable conductivity at low frequency deriving from transitions between localized states inside the impurity band. Although electron transport in electronic glasses is still not completely understood, different regimes for AC transport can be distinguished depending on the strength of electron-electron interactions, the energy scale being probed and the amount of disorder. See Helgren *et al.* (65) for a complete discussion on this subject.

Far away from the MIT and in regimes when electron-electron interactions are not significant, one considers a

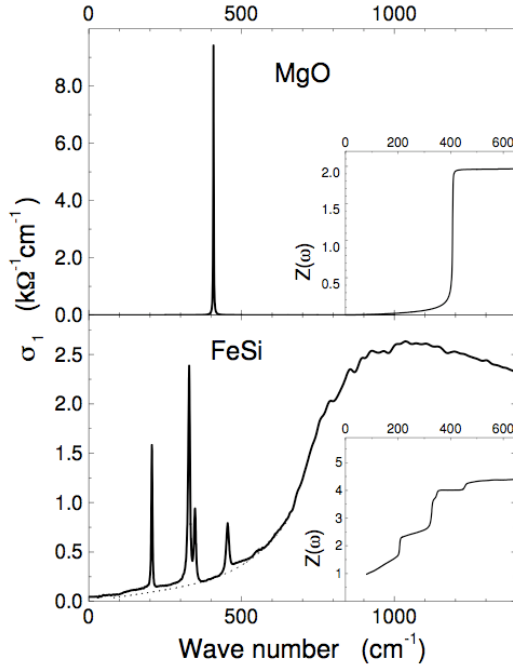


FIG. 23 Optical conductivity of MgO (top panel) and FeSi at $T=4K$ (bottom panel) showing the strong phonon absorption found in such insulating compounds. In the insets are the integrated spectral expressed in units of effective charge (See Sec. V.A), with the electronic contribution removed. For MgO the effective measured *transverse charge* is 1.99, which is in good agreement with the formal valences of the Mg^{+2} and O^{-2} ions. From Ref. (62). For further discussion on effective charge see Ref. (7).

so-called Fermi glass. This is an ensemble of localized charges whose properties are primarily determined by Fermi statistics. When the long-range Coulomb interaction is of the same order as the disorder potentials, a so-called Coulomb glass emerges, and finally, near the transition to the metallic state, fluctuations lead to a quantum critical regime. For these various regimes, certain characteristic power law and exponential functional forms for the AC and DC transport are expected. For instance, in a Fermi glass the AC conductivity is expected to be a power law $\sigma \propto \omega^2$ (66). In a Coulomb glass the conductivity is expected to take the form $\sigma \propto U(r) \cdot \omega + \omega^2$ (67). Here, the non-interacting Fermi glass functional form is returned at high frequencies, but a linear dependence is found at low frequencies. The crossover between these regimes is smooth and set by $U(r)$ which is the typical long range interaction strength between the charges forming the absorbing resonant pair. There are expected to be logarithmic corrections to these power laws. As the energy scale $U(r)$ characterizes the long range Coulomb interaction, it is expected to go to zero at the MIT. As one approaches the quantum critical point, the behavior may also be interpreted using scaling laws (discussed below) that connect the temperature, frequency and concentra-

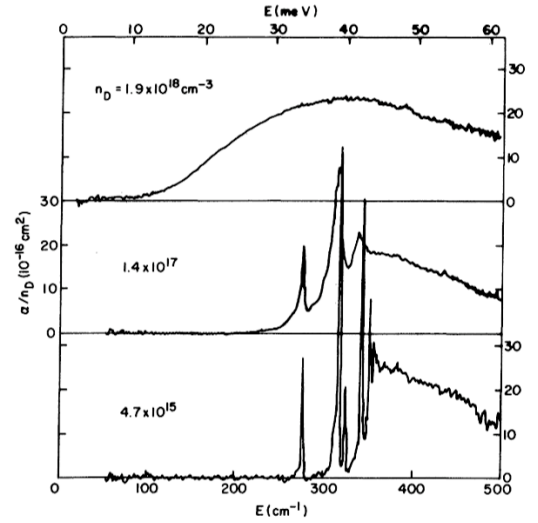


FIG. 24 Absorption coefficient in P doped Si normalized to the number of donors n_D for the three different labeled doping levels at 2 K. At the lowest doping, absorptions due to individual donor atoms can be seen. These absorption broaden into a impurity band at higher dopings. The direct gap is at much higher energies as shown in Fig. 25. From Ref. (63)

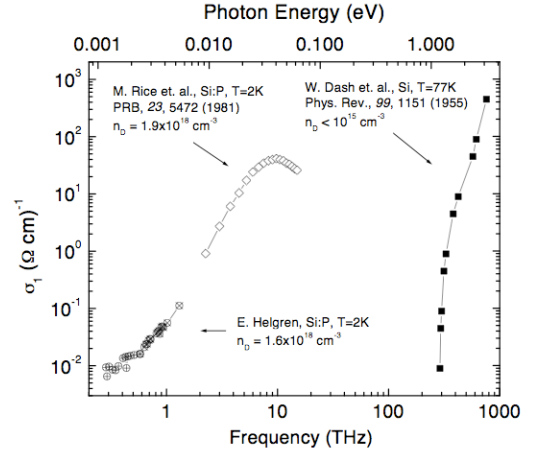


FIG. 25 Optical conductivity of silicon doped close to the 3D metal-insulator transition. The optical band gap is visible *via* the high energy onset at 1.12 eV. The intermediate energy conductivity is associated with excitations from the dopant band to the conduction band. The conductivity at the lowest energies, i.e. photon assisted hopping conductivity, is due to intra-dopant band excitations. From Ref. (65).

tion dependence of the response. It is expected that there is a correspondence between the frequency and temperature dependent conductivity on both sides of the critical concentration. Such an analysis of the conductivity leads to a universal scaling function and defines critical exponents as discussed below.

In Fig. 26, the pioneering data of Stutzmann and Lee

(31) on Si:B demonstrates the real part of the conductivity measured with a broad band microwave Corbino spectrometer. The data shows a remarkable observation of conductivity linear in frequency at low frequencies and a sharp crossover at $U(r)$ to ω^2 at high frequencies. Work on Si:P on samples farther from the metal-insulator transition shows the same behavior (64; 65), albeit the energy scale of the crossover is found at higher energies as it is set by the long range Coulomb interactions (which increases away from the MIT). Although the proposed functional form of Efros and Shklovskii approximately fits the data of Stutzmann and Lee (31) (and of Helgren *et al.* (64)), it fails to account for the very sharp crossover between power laws. Stutzmann and Lee (31) interpreted the sharp crossover as deriving from a sharp feature in the density of states - the Coulomb gap (a depression at the Fermi energy in the density of states that is a consequence of the long range Coulomb interaction). However, such an interpretation is at odds with theory and moreover, was not consistent with the work of Helgren *et al.* (64), where it was shown that the crossover was set by the typical interaction strength. The sharp transition between power laws remains unexplained; although one may consider that this sharp crossover may arise from collective effects in electron motion (69).

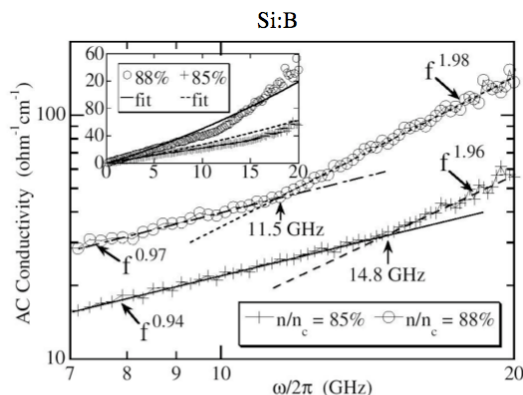


FIG. 26 The real part of the complex frequency dependent conductivity for two samples of Si:B at 85% and 88% of the way to metal-insulator transition (31). Data has been measured up to 20 GHz with a Corbino geometry microwave probe. The crossover in the frequency dependent conductivity from linear to quadratic is qualitatively consistent with a crossover from Coulomb glass to Fermi glass behavior.

The theoretical functional form and experimental observation is remarkable, because the ordering of regimes is at odds with the typical situation in solid state physics. Typically it is that non-interacting functional forms are expected at low frequency and temperature, while the explicit effects of interactions are seen at higher frequencies. The canonical example of this ordering is the Fermi liquid, where it is the low frequency spectra which can be typically modeled in terms of quasi-free non-interacting particles (perhaps with renormalized masses).

The higher energy spectra are typically more complicated and show the non-trivial effects of electron-electron and electron-boson interactions. Similar physics is exhibited in the heavy-fermion compounds in that it is the low frequency regime that can be understood in terms of conventional Boltzmann transport of heavy electrons. In contrast, in electron glasses, it is the low frequency spectra which shows the effect of interactions while the high frequency spectra returns the non-interacting functional form.

This was not the original expectation. Anderson originally coined the term “Fermi glass” in analogy with the Fermi liquid, to describe an ensemble of localized charges whose properties were largely determined by Fermi statistics alone (70).

“(The) Fermi liquid theorem is a rigorous consequence of the exclusion principle, it happens because the phase space available for real interactions decreases so rapidly (as E^2 or T^2). The theorem is equally true for the localized case: at sufficiently low temperatures or frequencies the non-interacting theory must be correct, even though the interactions are not particularly small or short range: thus the non-interacting theory is physically correct: the electrons can form a Fermi glass.”

– P.W. Anderson, 1970

It is surprising that even in a material as thoroughly studied as doped bulk silicon that there exists no clear consensus as to the ground state and the nature of the low energy excitations at low dopings. It appears however, that Anderson’s speculation is not borne out by the experimental situation. The low lying excitations appear fundamentally changed by interactions. Of course, existing experiments do not preclude that at even lower energies the Coulomb glass-like behavior will not break down or give way to a different response like a Fermi glass.

D. Mott insulators

Mott insulators differ from band insulators and Anderson insulators in that their insulating effects derive from correlations and not from filled bands or disorder-driven localization. One expects to see very interesting aspects of spectral weight transfer from high energies to low as charges are doped into them and they eventually become metals.

At half-filling it is believed that such Mott insulators are characterized by upper and lower Hubbard bands, which are split by an energy U that is the energy to doubly occupy a single site. If one wants to occupy a site doubly, one must pay this energy cost U . As will be discussed below the spectral weight $\int \sigma(\omega) d\omega$ is a conserved quantity which depends on the total amount of charge in

a system. It is interesting to account for how spectral weight is transferred from high to low energies by doping electrons into such a system (71).

At half-filling, the lower Hubbard band is filled (occupied) and the upper Hubbard band is unfilled. Since every site in the system has one electron, the spectral weight of upper and lower Hubbard bands are equal. Now consider the situation after one dopes a single electron to the upper Hubbard band. The *unoccupied* spectral weight of the upper Hubbard band reflects the total number of sites which can have an electron added, the lower Hubbard band reflects the total number of sites *occupied* by a single electron, and the *occupied* weight of the upper Hubbard band reflects the total number of sites that are doubly occupied. These considerations then mean that doping a single electron transfers one state each from both upper and lower Hubbard bands as shown in Fig. 27 because doping changes the number of sites which are occupied/unoccupied. It is natural to expect that a state is removed from the *unoccupied* part of the upper Hubbard band as now a state is *occupied*. However a state is also removed from the *occupied* part of the lower Hubbard band as its spectral weight quantifies how many electrons sit on singly *occupied* sites (and hence how many can be removed from singly *occupied* sites). The *occupied* weight of the upper Hubbard band is then '2', and the spectral weights of *occupied* lower Hubbard band and *unoccupied* upper Hubbard band are both $N-1$. The situation differs from doping a band semiconductor because then doping a single electron into the upper band, only takes that single state from the upper band. There is no transfer of spectral weight across the gap. An intermediate case is expected for the charge-transfer insulators, which the parent compounds of the high T_c superconductors are believed to be. In these compounds a charge transfer band (consisting primarily of $O\ 2p$ states) sits in the gap between upper and lower Hubbard bands and plays the role of an effective lower Hubbard band. The energy to transfer charge from from an oxygen to copper Δ becomes the effective onsite Hubbard U . Issues of spectral weight transfer in Hubbard and charge transfer insulators are discussed more completely in Ref. (71).

In Fig. 28 we show the doping dependence of the room temperature optical conductivity of $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$. At $x = 0$ the spectra show a clear charge transfer gap of about 1.8 eV. This largely reflects excitations from $O\ 2p^6$ states to $\text{Cu}\ 3d^{10}$. Upon doping with holes, spectral weight is observed to move from the high energies to low in a manner consistent with the picture for the charge transfer/Mott Hubbard insulators in Fig. 27. It is interesting to note that a remnant of the charge transfer band remains even for samples that have become superconductors and are known to have a large Fermi surface.

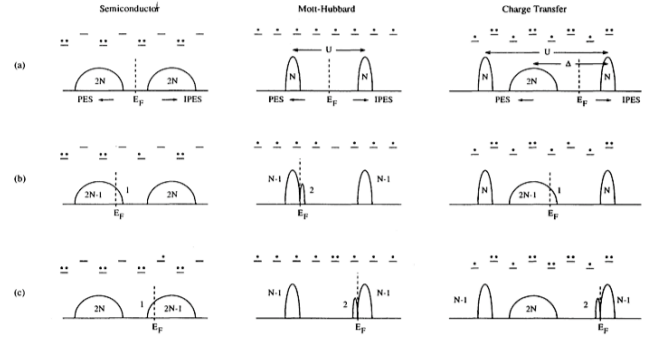


FIG. 27 A schematic of the electron-removal and addition spectra for a simple semiconductor (left), a Mott-Hubbard system in the localized limit (middle) and a charge transfer system in the localized limit. (a) Undoped (half-filled) (b) one-electron doped, and (c) one-hole doped. The onsite repulsion U and the charge-transfer energy Δ are indicated. From Ref. (71).

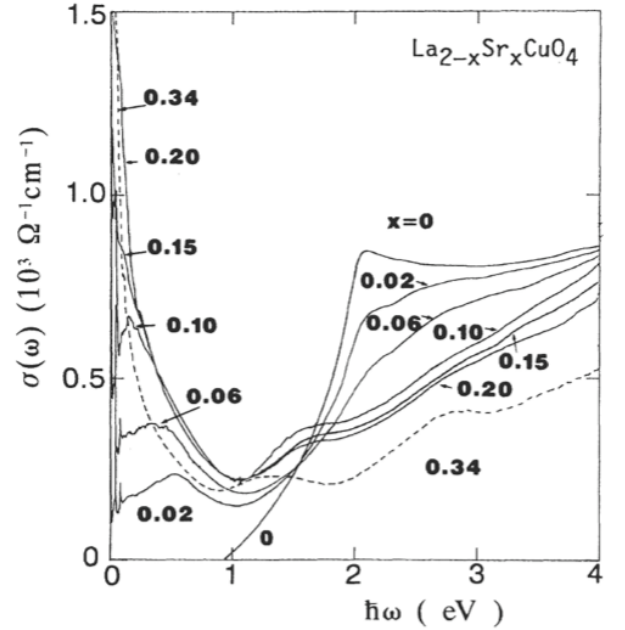


FIG. 28 Doping dependence of the room temperature optical conductivity of $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$. At $x = 0$ the spectra show a clear charge transfer gap of about 1.8 eV. Upon doping with holes, spectral weight is observed to move from the high energies to low in a manner consistent with Fig. 27. Figure adapted from (72).

E. Superconductors and other BCS-like states

One can get a rough intuition of the electrodynamic response of superconductors for $\hbar\omega \ll 2\Delta$ and $T \ll T_c$ from the relations in Eq. 25, which give the dissipationless limit for the Drude model. One expects a δ function peak at zero frequency in the real conductivity and a

$1/\omega$ dependence in the imaginary part, whose coefficient is set by the strength of the δ function. At frequencies on the order of the superconducting gap 2Δ , Cooper pairs can be broken and enhanced absorption should be found. At higher temperatures, thermally excited quasiparticles are created and one expects that as they are subject to essentially normal state dissipative processes, they will give a contribution to σ_1 at finite ω .

Very roughly one expects a two fluid scenario where the conductivity is approximately given by $\sigma(\omega) = \frac{\pi N e^2}{2m} \delta(\omega = 0) + i \frac{N(T) e^2}{m\omega} + \sigma_{1n}(\omega, T)$ where σ_{1n} is a normal fluid component. At low temperatures, one expects that the superfluid density $N(T)$ is degraded as $1 - e^{-\Delta/k_B T}$, as Cooper pairs thermally disassociate. As the superfluid density decreases the normal fluid component increases and one may in some circumstances expect an increase in σ_{1n} to go as $e^{-\Delta/k_B T}$.

These above considerations are only approximate however. The explicit temperature dependence of the gap and the mutual screening effects of the superfluid and normal fluid must be taken into account. Among other things, this means that the functional form of the contribution from ‘normal’ electrons σ_n , although still peaked at $\omega = 0$, will be decidedly non-Lorentzian. Within the context of the BCS theory the response of a superconductor can be calculated from the Mattis-Bardeen formalism. I will not go into the details of the calculation here. Interested readers should consult Tinkham (5). One of the important results from this formalism however is the effect of the superconducting coherence factors, which depending on their sign can lead to enhanced or suppressed absorption over the normal state above and/or below the gap edge. This means that different symmetries of the superconducting order parameter (or order parameters of other BCS-like condensates like spin- or charge-density waves), leave their signatures on the dissipative response.

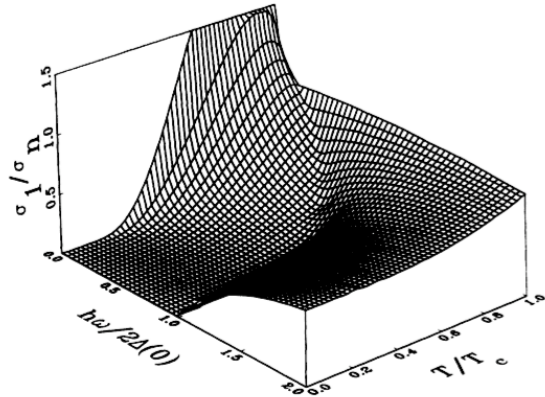


FIG. 29 Temperature and frequency dependence of the conductivity σ_1 as evaluated from the Mattis-Bardeen expression. The coherence peak exists only at low frequencies $\hbar\omega/2\Delta < 0.1$. The cusp in the surface corresponds to the energy gap. From Ref. (75).

Shown in Fig. 29 is the temperature and frequency dependence of the real part of the conductivity σ_1 for $\omega > 0$ as evaluated from the Mattis-Bardeen expression for ‘type II’ coherence factors, which are appropriate for s-wave superconductivity. One can see that at $T=0$, one has no below gap absorption, and then a gentle rise begins starting at the gap edge 2Δ . Despite the singularity in the density of states, the conductivity is suppressed at the gap edge, as the type II coherence factors effectively cancel the enhanced density of states. As one warms the sample, below gap excitations are possible from thermally excited quasiparticles. Just as above the gap edge the absorption is suppressed, the absorption is enhanced over the normal state at energies below the gap. This is again the consequence of type II coherence factors.

This anomalous behavior is more clear along the temperature axis. If one follows the conductivity at a particular frequency as a function of temperature, one will see an enhanced absorbance at temperatures below T_c . This result although surprising is direct evidence for coherence effects in the superconductor. An analogous enhancement found in the nuclear relaxation rate *via* NMR - the so-called Hebel-Schlichter peak - was early evidence for the BCS theory (73).

These features contrast with the situation in Type I coherence factors as shown in Fig. 30. In a Type I coherence factor SDW material one expects a very different response. There the coherence factors don’t cancel the singularity in the density of states. Likewise, there is no Hebel-Schlichter-like peak in the temperature dependence.

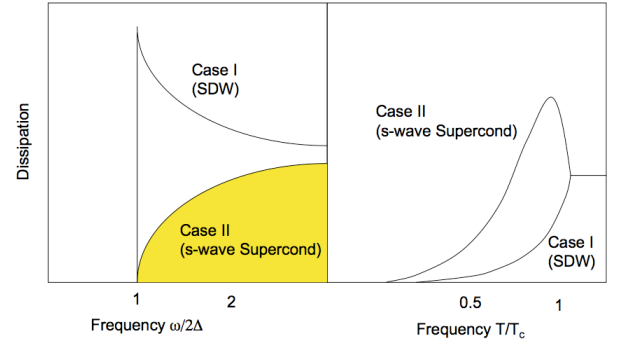


FIG. 30 (Color) (left) Approximate frequency dependence of the dissipation rate from the Mattis-Bardeen theory for Type I and Type II coherence factors. (right) Approximate temperature dependence of the dissipation rate for $\omega = 0.1\Delta$ for both coherence factors.

Qualitatively the behavior for Type II coherence factors is realized in conventional s-wave superconductors. In Fig. 31, the normal state normalized conductivity from some of the original measurements of Palmer and Tinkham (74) is shown, which is in good agreement with the Mattis-Bardeen prediction. The suppression at the gap edge is consistent with type II coherence factors and hence a s-wave superconducting state. Mattis-Bardeen predicts that subgap absorptions rise with increasing

temperature and become enhanced over the normal state conductivity.

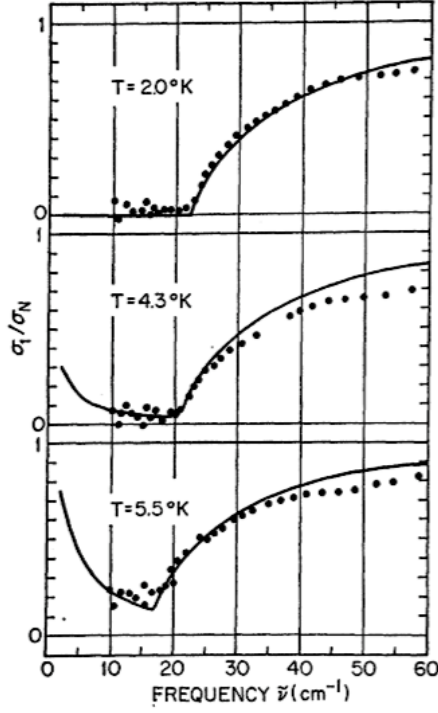


FIG. 31 Frequency dependence of the normalized conductivity through lead films at three different temperatures. The results are obtained through a combination of reflection and transmission measurements. The solid line is a calculation using the Mattis-Bardeen theory with a $2\Delta/\hbar = 22.5 \text{ cm}^{-1}$. T_c for these lead films is $7.2 \pm 0.2 \text{ K}$. From Ref. (74).

In Fig. 32 the conductivity of Nb at 60 GHz as measured in a microwave resonance cavity is shown as a function of temperature (75). The peak below T_c is the electromagnetic equivalent of the Hebel-Schlichter peak in NMR. This is again consistent with s-wave superconductivity.

As noted, different behavior is expected for type I coherence factors. There one expects an absorption enhancement at the gap edge and no ‘Hebel-Schlichter’ peak. The lack of such a peak in electromagnetic absorption of cuprate superconductors is at least partial evidence for *d*-wave superconductivity in those compounds. It is due in part to the lack of a strong singularity in the *d*-wave density of states, but also because the coherence factor vanishes for $q = \pi, \pi$ since $\Delta_k \approx -\Delta_{k+\pi, \pi}$ for k near $\pi, 0$. Such data is shown in Fig. 33 where the conductivity measured at a number of different frequencies in the GHz range on YBCO is displayed as a function of temperature (76). The data shows a broad peak in σ_1 at around approximately 35 K, but a comparison with the Mattis-Bardeen prediction shows that it is incapable of describing it as the rise in σ_1 is much more gradual than predicted. An explicit comparison is shown in Fig. 34. This peak has been quite reasonably described in terms

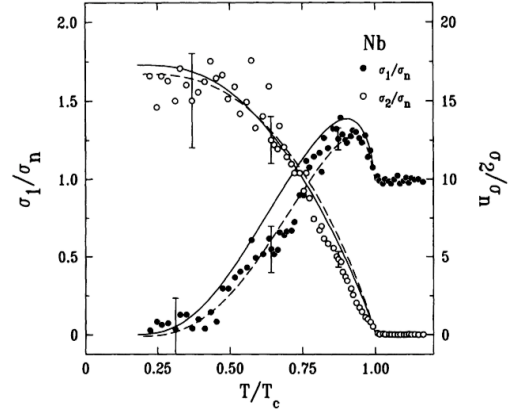


FIG. 32 Temperature dependence of the complex conductivity $\sigma(\omega)$ of Nb as evaluated from surface impedance measurements at 60 GHz in cavities. The solid curve is the weak coupling Mattis-Bardeen prediction. The dashed curve is a strong coupling Eliashberg prediction. From Ref. (75).

of a collapsing scattering rate below T_c of quasiparticles whose number remains appreciable until low temperatures due to the *d*-wave nature of this compound. An examination of the Drude model shows that in general one expects a peak in σ_1 when the probe frequency is approximately equal to $1/\tau$ the scattering rate. The exhibited peak is therefore not a Hebel-Schlichter peak, and the data is consistent with *d*-wave superconductivity. These experiments give evidence for *d*-wave superconductivity twice: the lack of a Hebel-Schlichter peak and the large σ_1 due to quasiparticle effects. Note that the other sharp peak right at T_c is believed to be due to fluctuations of superconductivity. Its functional form is also inconsistent with it being a Hebel-Schlichter peak.

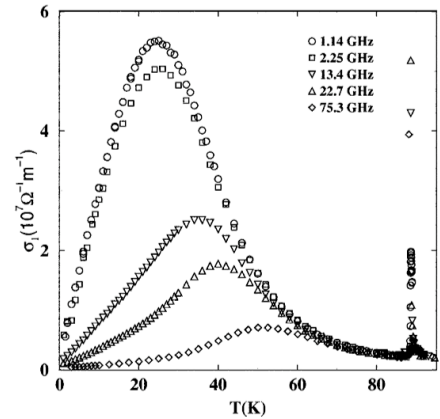


FIG. 33 The real part of the conductivity extracted from the microwave surface resistance of YBCO at a number of different GHz frequencies. From (76).

For completeness, I should mention that spin density wave compounds which can be treated within the BCS

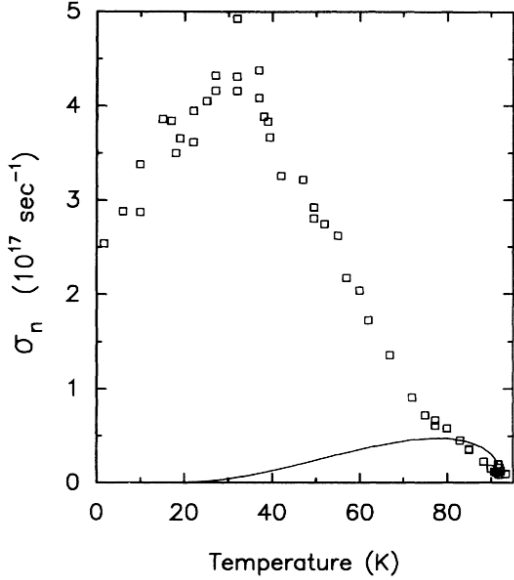


FIG. 34 The real part of the conductivity extracted from the microwave surface resistance of YBCO. The BCS conductivity (solid) is calculated using a T_c of 91.8 K, a gap ratio of 3.52, and various other physical parameters such as penetration depth, coherence length, and mean free path. It is completely incapable of describing the EM response, which shows the d -wave nature of these materials. From Ref. (77).

formalism are expected to have a type I order parameter and a gap edge absorption enhancement. In many cases they can also be treated within a BCS formalism. See Ref. (78) for explicit details.

A vast literature exists on the electrodynamics of superconductors. I have given only the most superficial treatment here. Many considerations go into how superconductivity is exhibited in optical spectra. See Tinkham (5), for instance, for in-depth discussions on the clean and dirty limits of superconductivity and Basov and Timusk (9) for the state-of-the-art on high-temperature cuprate superconductivity.

V. ADVANCED ANALYSIS

A. Sum Rules

The optical constants satisfy a number of different sum rules (3). The most frequently used sum over the real conductivity is the one that will be discussed in detail here. As alluded to above, there is a relation for the integral over all frequencies of the real part of the conductivity to the total number of charges n and their mass m_e .

$$8 \int_0^\infty \sigma_1(\omega) d\omega = \frac{4\pi n e^2}{m_e}. \quad (51)$$

Analysis of data in terms of sum rules provides a powerful tool that can be used to study spectral weight distributions in a relatively model-free fashion. The above integral which extends from zero to infinity is the *global oscillator strength sum rule*, which relates the integral of the σ_1 to the density of particles and their bare mass. It is related to the oscillator strength $f_{s,s'}$ discussed above in the context of the Kubo formula. Both are manifestations of the f -sum rule of elementary quantum mechanics. Sum rules follow as consequence analyticity of the response functions and causality. See Refs. (1; 3) for a few derivations.

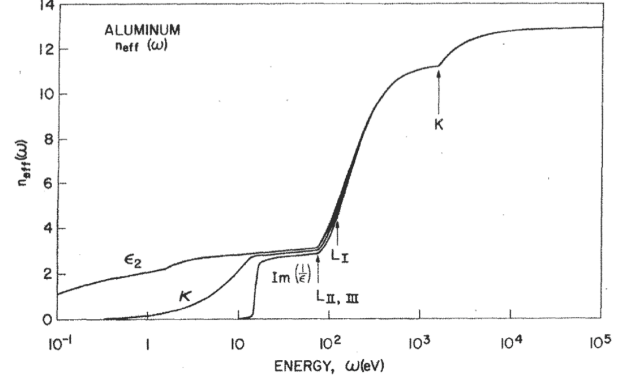


FIG. 35 The effective number of carriers $n_{eff}(\Omega_c)$ as a function of cutoff frequency Ω_c for Aluminum. A number of different sum rules are investigated and displayed. The sum rule for ϵ_2 is equivalent to the sum rule expressed in Eq. 51. Figure adapted from Ref. (79).

In real systems the integral to infinite frequencies is rarely utilized in practice and we are usually more concerned with partial sum rules such as

$$8 \int_0^W \sigma_1(\omega) d\omega = \frac{4\pi n e^2}{m_b}. \quad (52)$$

where W is the unrenormalized electronic bandwidth and m_b is the band mass. Sum rules of this fashion can be used to get information about occupation and correlation in a subset of bands. Of course if the integral cut-off W is extended to high enough energies the full sum rule Eq. 51 must be fulfilled. This puts a fundamental constraint on the various values that the individual sub-band band masses can assume. A partial sum rule analysis of the equivalent quantity ϵ_2 applied to the simple metal case of aluminum is shown in Fig. 35. Aluminum's nominal electronic configuration is $1s^2 2s^2 2p^6 3s^2 3p^1$. Depending on the cutoff of the integral, the sum rule for different orbitals is satisfied. Integrating up to approximately the plasma frequency (15.5 eV) returns the number of electrons in the $n = 3$ valence band. At the x-ray L edge at around 100 eV, one begins to reveal spectral weight of the $n = 2$ formed bands. One can see that if the integral is performed to high enough energies (well above the K

edge of aluminum) one recovers the aluminum's atomic number '13' if one assumes the free-electron mass in Eq. 52. It is interesting to note that the rate of convergence is different for the different sum rules plotted. This is related to how spectral is distributed in the spectra and can be related to quantities like the strength of interactions.

In correlated systems one frequently makes use of an even more limited sum rule and only performs the integral over an energy only several times the Drude width to determine the mass renormalized due to interactions. For instance the small spectral weight in the very narrow Drude peak as shown in Fig. 8 gives a very large mass ($\approx 10^2 m_e$). An integral as such over a small renormalized Drude peak with small spectral weight is how the very large masses in Fig. 4 were generated. One can view this small mass as coming from a very narrow interaction derived band where the integral only has to be performed over a small fraction of W to capture its spectral weight. However, the sum rules of Eqs. 51 and 52 must ultimately be satisfied at high enough energies. This means that there must be some higher energy satellite in σ_1 that contains enough spectral weight to return the band mass m_b when the integral in Eq. 52 is performed out to the unrenormalized band width W . Note that similar information can be gained from applying the extended Drude model analysis, which is outlined in the next section (Sec. V.B).

Sum rules have been used extensively in the analysis of the data for correlated electron systems because, in some circumstances, they allow a relatively model independent way to analyze the data. For instance, one can show that for a tight binding model with nearest neighbor hopping only that

$$8 \int_0^W \sigma_1(\omega) d\omega = -\frac{\pi e^2 a_r}{2\hbar^2} K_r. \quad (53)$$

where a_r is the lattice constance in the incident E field's polarization direction and K_r is the effective kinetic energy. This relation has been used extensively in the cuprate superconductors to attempt to show evidence for or against a novel lowering of the kinetic energy-driven mechanism for superconductivity. This is in contrast to the usual mechanism in the BCS theory where it is the potential energy that drops when falling into the superconducting state. Such analysis is not trivial in these materials, as there is evidence that the spectral weight that goes into the condensate is derived not just from the near E_F electronic band over a width much smaller than W , but over an energy range many times the band width W ¹⁰.

¹⁰ It may be that this extreme mixing of low and high energy scales between, which prohibits a true low energy description is an alternative definition of a correlated material.

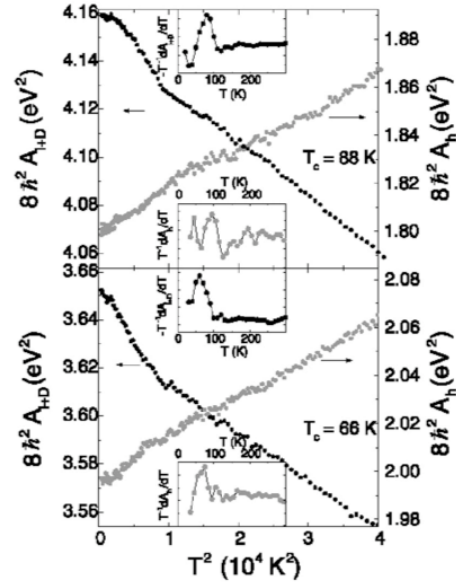


FIG. 36 Temperature dependence of the low-frequency spectral weight $A_{1+D}(T)$ and the high-frequency spectral weight $A_h(T)$, for optimally doped and underdoped Bi2212. Insets: derivatives $-T^{-1}dA_{1+D}/dT$ and $-T^{-1}dA_h/dT$. From Ref. (80).

It is believed that the usual sum rule for superconductors (Ferrell-Glover-Tinkham) (5) is satisfied for the ab plane conductivity of the cuprate superconductors up to about 10% accuracy (9). Molegraaf *et al.* (80) used a combination of reflectivity and spectroscopic ellipsometry in Bi2212 (Fig. 36) to conclude that about 0.2 - 0.3% of the total strength of the superconducting δ function is collected from an energy range beyond 10,000 cm^{-1} to 20,000 cm^{-1} ¹¹ and that the kinetic energy decreases in the superconducting state. This is a very small effect, but still large enough to account for the condensation energy. Such analysis of total spectral weight transfer can be tricky as it requires the analysis of spectral weight beyond the measurement regime, which is only constrained through the Kramers-Kronning relations. These results or rather the analysis of the data has been disputed by Boris *et al.*, (81) who form a nearly opposite conclusion regarding spectral weight transfer based on nearly identical experimental data.

The c-axis response has been investigated in a similar manner and a similar transfer of spectral weight from very high energies to the δ function has been observed, although in this case the magnitude of the effect is defini-

¹¹ 10,000 cm^{-1} is approximately equivalent to 1.24 eV and 14,390 K! It is remarkable that such energy scales are explicitly relevant for a 100 K phenomenon. In contrast conventional superconductors satisfy the 'Ferrell-Glover-Tinkham' sum rule at energies approximately 10 - 20 Δ (5).

tively insufficient to account for T_c (9).

As mentioned above, there are a number of sum rules in addition to the most commonly applied one for σ_1 (or equivalently the first moment sum of ϵ_2). Probably next most commonly applied is the sum rule for the first moment of the loss function, whose integral is equal to that for the first moment sum of ϵ_2 (3). This has been called the longitudinal f -sum rule. A similar sum rule concerns the first moment sum of the absorption coefficient $\kappa(\omega)$ (79). There is also a sum rule on the loss function itself, that can be related to the Coulomb correlation energy of the ground state wavefunction (82; 83). Similarly, there is second moment conductivity sum rule and a third moment loss function sum rule that in certain circumstances allows one to evaluate the strength of Umklapp scattering and the static electron-lattice energy (84; 85). There are also first *inverse* moment sum rules for the conductivity and loss function, which are equal to various combinations of pure numbers (For instance $\int_{-\infty}^{\infty} -\text{Im} \frac{1}{\omega\epsilon(\omega)} d\omega = \pi$). These allow the calibration of, for example, the absolute intensity of an electron energy loss measurement since these sums have no dependence on any material parameters. Other related sum rules include the inertial sum rule on the index of refraction ($\int_0^{\infty} [n(\omega) - 1] d\omega = 0$) (86; 87; 88) and the “DC sum rule” on the dielectric function ($\int_0^{\infty} [\epsilon_1(\omega) - 1] d\omega = -2\pi^2 \sigma_{DC}$) (86; 87). There is also a sum rule on the frequency dependent scattering rate (95), which is discussed below. For further details on sum rules, see the very extensive literature on this subject (3; 7; 79; 82; 83; 84; 85; 86; 87; 88; 95).

B. Extended Drude Model

Within the Drude-Lorentz (Sec. II.B) model we consider that conduction electrons are quasi-free. The scattering rate of the Drude intraband contribution is considered to be characterized by a single frequency independent relaxation time τ . It is well known however that various inelastic channels can contribute to relaxation in solids, each with a characteristic frequency dependence. For instance, in 3D the fermion-fermion scattering rate is expected to exhibit an ω^2 dependence at low frequency. An electron scattering off an Einstein boson (a single spectral mode with a well-defined frequency ω_0) is expected to show an onset in scattering at the boson frequency ω_0 which is the threshold to make a real (as opposed to virtual) excitation.

Allen and Mikkelsen (89) proposed that one could capture these frequency dependences in optical spectra through an *extended Drude model* (EDM) where the mass and scattering rate are explicitly frequency dependent. Inverting the complex conductivity one gets

$$\frac{m^*(\omega)}{m_b} = -\frac{\omega_p^2}{4\pi\omega} \text{Im} \left[\frac{1}{\sigma(\omega)} \right], \quad (54)$$

$$\frac{1}{\tau(\omega)} = \frac{\omega_p^2}{4\pi} \text{Re} \left[\frac{1}{\sigma(\omega)} \right], \quad (55)$$

where m_b is the band mass.

Both in spirit and formalism this is equivalent to standard treatments in many-body physics where one posits that the effects of interactions can be captured by shifting the energy of an added electron from the bare non-interacting energy $\epsilon(\mathbf{k})$ by a complex *self-energy* $\Sigma(\omega, \mathbf{k}) = \Sigma_1(\omega, \mathbf{k}) + i\Sigma_2(\omega, \mathbf{k})$. One can express the optical response in terms of the complex self-energy $\Sigma^{op}(\omega) = \Sigma_1^{op}(\omega) + i\Sigma_2^{op}(\omega)$ as

$$\sigma(\omega) = -i \frac{\omega_p^2}{4\pi(2\Sigma^{op}(\omega) - \omega)}. \quad (56)$$

and in terms of previously defined quantities

$$\begin{aligned} \Sigma_1^{op} &= \frac{\omega}{2}(1 - m^*/m_b), \\ \Sigma_2^{op} &= -\frac{1}{2\tau(\omega)}. \end{aligned} \quad (57)$$

A caveat should be given about the interpretation of optical self-energies. Although an identification can be made with the quasi-particle self-energies that appear in one-particle spectral functions, the two self-energies are not exactly the same. While quasi-particle scattering depends only on the total charge scattering rate to all final states, transport and optics experiments have a much larger contribution from backward scattering than forward scattering as it degrades the momentum much more efficiently. In general this means that the quantities derived *via* optics emphasize backward scattering over forward scattering and so the optically derived quantities can contain a vertex correction not included in the full quasi-particle interaction. In this sense the two self-energies are formally different although they can contain much of the same information.

Frequently the extended Drude model will be introduced in terms of a complex frequency dependent *Memory* function, $M(\omega) = 1/\tau(\omega) - i\omega\lambda(\omega)$, where τ is the lifetime and $1 + \lambda = m^*/m_b$

$$\sigma(\omega) = \frac{\omega_p^2}{4\pi(M(\omega) - i\omega)}, \quad (58)$$

$$\sigma(\omega) = \frac{\omega_p^2}{4\pi(1/\tau(\omega) - i\omega[1 + \lambda(\omega)])}. \quad (59)$$

One can put Eq. 59 in the form of the standard Drude model with the substitutions $\tau^*(\omega) = [1 + \lambda(\omega)]\tau(\omega)$ and $\omega_p^{*2} = [1 + \lambda(\omega)]\omega_p^2$ to get

$$\sigma(\omega) = \frac{\omega_p^{*2}(\omega)}{4\pi} \frac{\tau^*(\omega)}{1 - i\omega\tau^*(\omega)}. \quad (60)$$

This equation describes the frequency dependence of a particle with renormalized plasma frequency (and hence renormalized mass) and renormalized scattering rate. Compare Eq. 60 with Eq. 26. Note that the quantity $1/\tau^*$ is not equivalent to the quantity defined in Eq. 55 above, as $1/\tau^*$ includes the renormalization effects of the lifetime as well as the mass, whereas $1/\tau$ includes only lifetime effects. The two quantities differ by a factor of $1 + \lambda(\omega)$. In this sense one may argue that $1/\tau(\omega)$ is the more intrinsic quantity, as also evidence by its direct proportionality to the imaginary part of the self-energy, but this point is essentially a semantic one. $1/\tau^*$ is the effective scattering rate (or dressed scattering rate) however, because for weak frequency dependence it is the actual half width of the Drude peak in the optical conductivity.

Various contributions to the total scattering rate such as electron-electron (ee), electron-phonon (ep), electron magnon (em), etc. add within the prescription set by Matthiesen's rule as $\frac{1}{\tau(\omega)} = \frac{1}{\tau_0} + \frac{1}{\tau_{ee}} + \frac{1}{\tau_{ep}} + \frac{1}{\tau_{em}}$. Note that there is typically also a contribution $\frac{1}{\tau_0}$ to the elastic scattering which is frequency independent that comes from static disorder. As mentioned above this can be seen as a measure of the degree to which the translational symmetry is broken by disorder and hence the degree to which strict momentum conservation in the optical selection rule $q = 0$ can be violated.

As $\frac{1}{\tau(\omega)}$ and $m^*(\omega)$ are a particular parameterization of the real and imaginary parts of a complex response function, they are Kramers-Kronig related. Analogous to the case of $\sigma(\omega)$ detailed above, if one knows $\frac{1}{\tau(\omega)}$ for all ω , then $m^*(\omega)$ can be calculated and vice versa.

The near- E_F electrons of the noble metals, like Cu, Ag, and Au have free-electron-like s -states, which form a Fermi surface that deviates from almost spherical symmetry only near the Brillouin zone necks in the $\langle 111 \rangle$ directions. The above analysis applied to such metals is shown in Fig. 37 and Fig. 38. For Cu and Ag the scattering rate shows an approximately ω^2 dependence of the scattering rate, which is in accord with the expectation for electron-electron scattering. It is interesting that electron-electron scattering is observed up to such high energies as we may have expected other contributions such as electron-phonon scattering also to give an observable contribution. We should reiterate that a purely translational invariant electron gas, cannot dissipate momentum by electron-electron collisions alone. In this regard effects like umklapp or interband (Baber) scattering are essential to see the effects of such collisions in the optical response. Also note here the difference between the bare scattering rate $1/\tau$ and the dressed scattering rate $1/\tau^*$. The difference is only significant when there is a large renormalization in the effective mass.

Note that in Eqs. 54 and 55 there is the matter of how to define the plasma frequency ω_p ¹². For the electron

gas the plasma frequency is given by $4\pi ne^2/m$, however the precise definition is less clear in a real material with interactions, interband transitions, and orbital mixing. In the above analysis ω_p must come from the spectral weight of the full intra-band contribution. Rigorously the plasma frequency should be defined from the sum rule Eq. 51 as

$$\int_0^\infty \sigma_1^{intra}(\omega) = \frac{\omega_p^2}{8}. \quad (61)$$

where σ_1^{intra} is contribution to the conductivity coming from all (and only) *intraband* spectral weight¹³. The integral extends all the way to infinity, which gives of course a practical difficulty in real systems because the value of the spectral weight will be contaminated by *interband* contributions. Note that for a complicated interacting system the integral and ω_p must include not only the contributions of the weight of the low frequency Drude peak, but must also include higher energy parts of the spectra (satellites) if they derive from the same non-interacting band. It can be difficult experimentally to estimate ω_p accurately. For instance, in the case of a system with strong electron-phonon coupling the spectra may be approximately modeled as the usual Drude model with a simple $\omega = 0$ Lorentzian and frequency independent scattering rate at low frequencies, but with a higher frequency satellite at the characteristic phonon frequency which results physically from the excitation of a *real* phonon as well as an electron-hole pair. The high frequency satellite manifests in the scattering rate as an onset at the phonon frequency as an additional decay channel becomes available at that energy. In this sense the plasma frequency which goes into an extended Drude analysis is the plasma frequency associated with the spectral weight of both the low frequency 'Drude' contribution *and* the satellite. The spectral weight of the low frequency part may be clear, but it may be a difficult practical matter to clearly identify the spectral weight of the satellite, due to the overlapping contributions of it with true interband transitions etc. In practice, a high frequency cutoff to the integral in Eq. 61 is usually set at some value which is believed to capture most of the intraband contribution, while minimizing contamination by interband transitions. A number of different criteria can be used: the requirement that the integral is temperature independent, an appeal to reliable band structure calculations etc. etc.

these expressions. Their functional dependence and form is independent of the choice of the plasma frequency.

¹³ Note that in anything other than a simple Drude system the plasma frequency here is not given by the plasma minimum in the reflectivity as that quantity is renormalized by a factor of $\frac{1}{\sqrt{\epsilon_\infty}}$. As mentioned above, this later quantity is known as the screened plasma frequency or plasmon frequency.

¹² Note that this is only important for the overall scale factor of

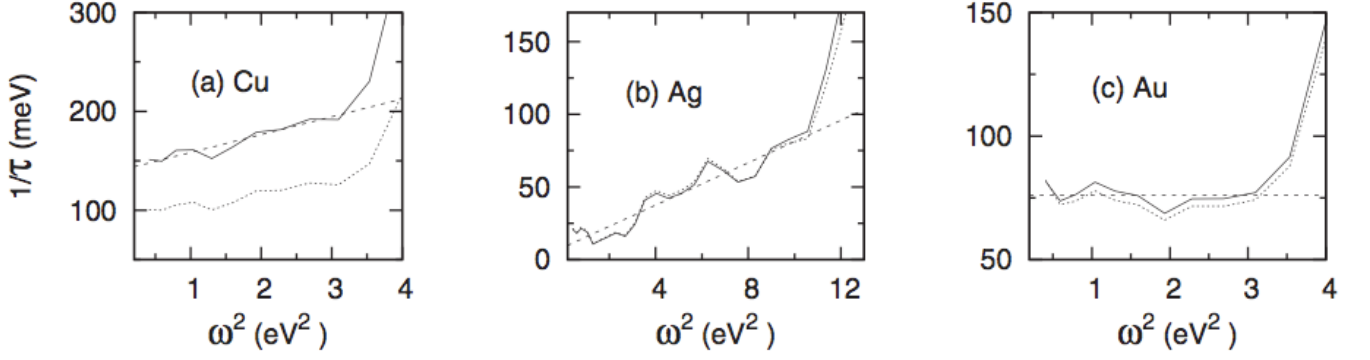


FIG. 37 Scattering rate vs. ω^2 of (a) Cu, (b) Ag and (c) Au. Solid and dotted lines are the bare scattering rate $1/\tau$ and the dressed scattering rate $1/\tau^*$ respectively as detailed in the text. From (90)

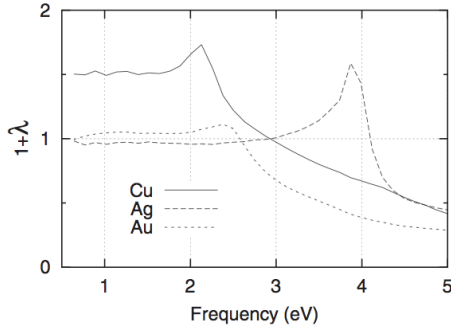


FIG. 38 Mass enhancement factor $1 + \lambda$ of noble metals. From (90)

There can also be a difficulty in definitions of the plasma frequency for systems described by the Mott-Hubbard model, where a strong onsite repulsion splits a single metallic band into upper and lower Hubbard ‘bands’. In such cases, one has one band or two depending on definitions and so the matter of the true intraband spectral weight can be poorly defined. In such cases it is important to remember that in this and other cases that the Drude model is a classical model applicable only to weakly interacting mobile particles. Although the EDM can be put on more rigorous ground expressing its quantities as optical self-energies, one still is always making an analogy and connection to a non-interacting system. To the extent that the EDM is just a parameterization of optical spectra, it is always valid. However, to the extent that its output can be interpreted as a real mass and scattering rate of *something* (i.e. a particle), it is important that that something exists. In other words, it must be valid to discuss the existence of well-defined electronic excitations in the Fermi-liquid sense in the energy regimes of interest.

In this regard, one must also be aware of the contribution of any interband terms in the evaluation of Eqs. 54 and 55. These expressions for the EDM are only valid

for excitations that are nominally $\omega = 0$. In principle finite frequency interband excitations (classically Drude-Lorentz) can overlap with a broad Drude intraband term giving artifacts that should not be considered as contributions to the scattering rate and effective mass. The sharp onset in $1/\tau(\omega)$ in Fig. 37 and the cusp in Fig. 38 are due to a onset of strong interband excitations in this spectral region (Fig. 19).

The EDM has been used in many different contexts in strongly correlated systems. An ideal example is afforded by its application to heavy fermion systems. As mentioned above, due to interaction of conduction electrons with localized moments the conduction electrons can undergo extremely large mass renormalizations of a factor of a few hundred over the free electron mass. These mass renormalizations develop below a coherence temperature T^* . Such effects are reflected in the optical spectra. As seen in Fig. 39, at high temperatures an EDM analysis of CeAl_3 reveals a pure Drude-like, essentially frequency independent mass and scattering rate. The conventionally sized mass and large scattering rate at high temperatures reflect the effects of essentially normal electrons scattering strongly and incoherently with the localized moments¹⁴. The spectra show no particularly interesting frequency dependence. Below the coherence temperature at low frequencies significant renormalizations to the mass and scattering rate are seen. The mass develops a significant enhancement and the scattering rate drops. The coherence temperature T^* and the frequency above which the unrenormalized values are recovered ω_c are equivalent to each other to within factors of order unity (with $\hbar = k_B = 1$). Remarkably the optical mass as compared to the band mass is increased by a

¹⁴ Note that the conventional EDM analysis expresses m^* as a ratio with the band mass m_b if ω_p is treated correctly as discussed above. This is in contrast to other techniques like, for instance, de Haas-van Alphen that expresses m^* as a ratio with the free electron mass m_e .

factor of almost 350. Note that although both the mass and the low frequency scattering rate undergo dramatic changes, the DC Drude conductivity is not changed significantly, as $\sigma_{DC} \propto \tau/m$ and the respective changes approximately cancel. This is reflected in the fact that the relation $m^*(\omega \rightarrow 0)/m_b$ is expected to be equivalent to $\tau/\tau^*(\omega \rightarrow 0)$ to within factors of order unity (11). Note that these changes in scattering rate and mass are reflected in the optical conductivity itself by the formation of a very sharp zero frequency mode (essentially a Drude peak) which rides on top of the normal Drude peak (11).

Evidence that the renormalizations in the optical mass reflect the existence of real heavy particles in these systems and not just a convenient parametrization of the optical spectral can be seen in the above discussed Fig. 4 which shows a proportionality of the optically measured mass to the linear coefficient of the specific heat (which is proportional to inverse of the near E_F density of states and hence the mass). It is remarkable that a parameter determined dynamically - essentially by shaking charge with an oscillating E-field - is precisely related to a quantity which is determined *thermodynamically* by quantifying the amount of heat absorbed. This graph provides a remarkable demonstration of the quasiparticle concept!

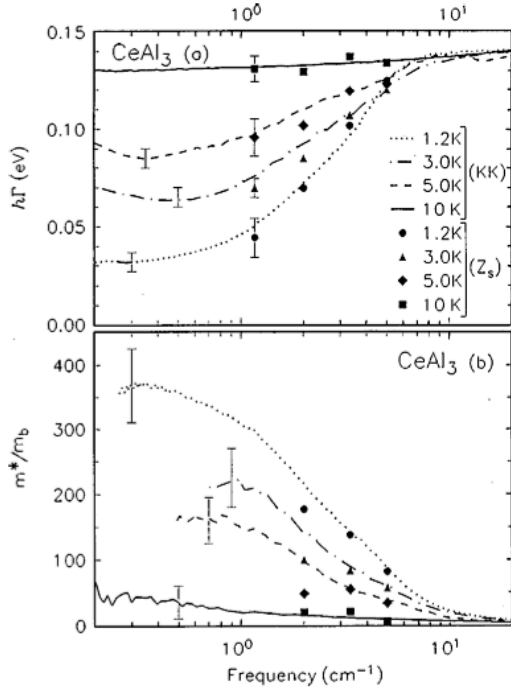


FIG. 39 Scattering rate and effective mass in CeAl₃. (a) Frequency-dependent optical scattering rate for CeAl₃ at four temperatures, compiled using both infrared reflectivity and microwave cavity data. (b) Frequency dependence of m^* obtained from Eq. 55 (93).

As mentioned, in addition to electron-electron scattering, the effects of electron-boson interactions also re-

veal themselves in the optical spectra. Spectral features in the optical conductivity deriving from electron-boson coupling were originally discussed in the context of Holstein processes - the creation of a real phonon and an electron-hole pair with the absorption of a photon - in superconducting Pb films (91; 92). The EDM analysis can reveal significant information about the interaction of electrons with various bosonic modes.

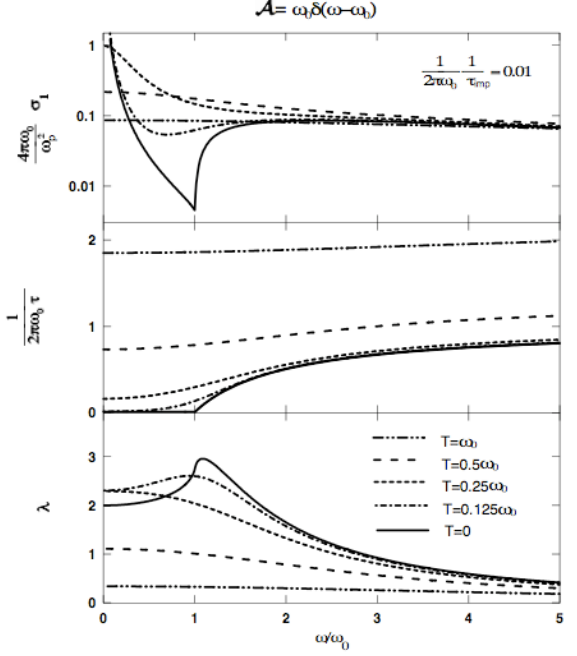


FIG. 40 Electron-boson model calculations with a boson spectral density $A(\Omega) = \omega_0\delta(\omega - \omega_0)$. The top panel gives the optical conductivity and the lower two panels show the corresponding scattering rate and mass enhancement. The coupling constant in this calculation is set to 1. From (94).

In Fig. 40 the optical conductivity calculated for an electron with impurity scattering coupled to a single Einstein phonon is shown for a few different temperatures. (See Puchkov, Allen, Shulga (94) for details regarding the calculation of the effects of electron-boson scattering in optical spectra.) The lower two panels show the scattering rate and mass enhancement generated from the optical conductivity. At low temperatures the optical conductivity (Fig. 40 (top)) reveals a sharp Drude peak at low frequencies, which results from the usual electron-hole excitations. The sharp onset in absorption at the phonon frequency is the threshold for excitation of a *real* phonon. At threshold, electron-hole pairs are excited additionally, but it is the phonon which carries away most of the energy. This is reflected in the scattering rate, which is flat and small at low ω , but shows a cusp and sudden increase at ω_0 as the phase space for scattering increases discontinuously (Fig. 40 (middle)).

Although real phonons can only be excited above threshold, electron-phonon coupling manifests itself at

energies below threshold by an increase in the effective mass (Fig. 40 (bottom)). Physically, this can be understood as a renormalization of the electron-hole pair energy modified by the excitation of *virtual* phonons. This renormalization of the energy manifests itself as an increased mass. The electron-hole pair can be viewed as dragging a cloud of virtual phonons with it.

One can get an approximate measure of the boson coupling function as (95)

$$\alpha^2 F(\omega) = \frac{1}{2\pi} \frac{d^2}{d\omega^2} [\omega \text{Re} \frac{1}{\sigma(\omega)}]. \quad (62)$$

Although the results of the calculation displayed in Fig. 40 is for phonons, the general idea holds for electron-boson coupling generically (95; 96) although, of course, the bosonic density of states is generally more complicated than a single sharp mode. Recently Tediosi *et al.* (97) found a remarkable example of this concept in semi-metal bismuth, where the bosonic excitation is formed out of the collective excitations of the electronic ensemble itself i.e. the plasmon. This is an effect that should be present in all metals, but is enhanced in a semi-metal like bismuth due to its very low carrier density and high $\epsilon_\infty \approx 100$. At low frequencies Tediosi *et al.* (97) found in their EDM analysis (Fig. 41) that the mass and scattering rate are approximately frequency independent as expected for the Drude model. However, at higher frequencies there is sharp onset in the scattering rate at a strongly temperature dependent position. As one cools bismuth, the charge density changes dramatically and the plasmon frequency (as given by the zero crossing of ϵ_1) drops by a factor of almost two. It was found that the energy scale of this sharp onset in scattering tracks the independently measured plasmon frequency as shown in Fig. 42. One can note the strong resemblance of the data to the calculation of an electron interacting with sharp mode in Fig. 40. A strong coupling as such between electrons and plasmonic electron degrees of freedom may in fact be captured within the same Holstein Hamiltonian that is used to treat the electron - longitudinal phonon coupling and describe polarons. For this reason this collective composite excitation has been called a *plasmaron* (98; 99) when exhibited in the single particle spectral function. The observation of Tediosi *et al.* was the first such observation optically.

EDM analysis has been applied extensively to the high- T_c cuprate superconductors (9). In Fig. 43 I show the imaginary and real parts of the optical self-energy as defined in Eq. 57 above for a series of four doping levels of the compound $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (100). The displayed samples span the doping range from the underdoped to the severely overdoped. Again one can notice the resemblance of the data to that of the model calculation in Fig. 40 and indeed data of this kind, along with similar signatures in angle-resolved photoemission have been interpreted as generic signatures of electron-boson interaction in the cuprates.

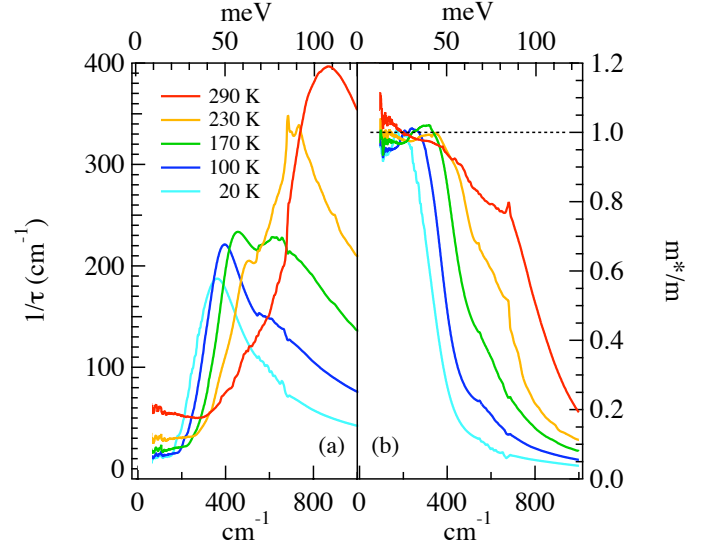


FIG. 41 (Color) Frequency dependent scattering rate (a) and effective mass (b), calculated from the optical data of elemental bismuth using ϵ_∞ . The low frequency scattering rate $\tau^{-1}(\omega)$ progressively falls as the temperature is lowered. An approximately frequency independent region is interrupted by a sharp onset in scattering and a decrease of the effective mass, which was associated with plasmon scattering.

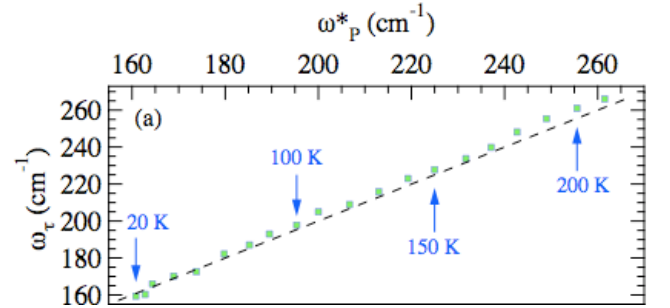


FIG. 42 (Color) A parametric plot of the sharp onset in scattering plotted versus the independently measured plasmon frequency in elemental bismuth. The plasmon frequency changes monotonically as the sample is cooled from room temperature to 15K.

The identity of this boson is a matter of intense current debate in the community. Some groups have pointed to a many-body electronic source(96; 100; 101; 102) related to the ‘41 meV’ magnetic resonance mode discovered via neutron scattering (103; 104). Others have argued that these feature’s presence above T_c , the relative doping independence of its energy scale, and its universality among material classes demonstrate a phononic origin and indicates the strong role that lattice effects have on the

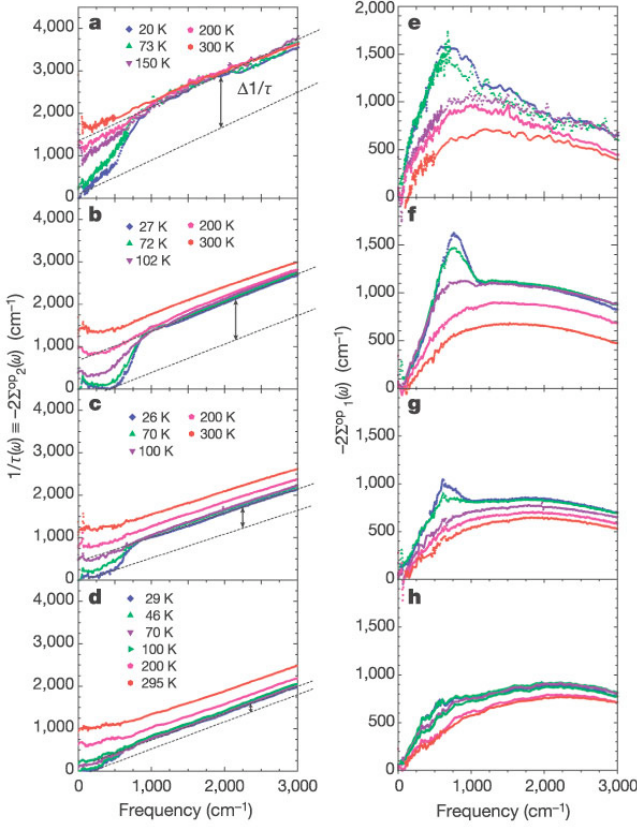


FIG. 43 (Color) a-d, The frequency and temperature dependent optical scattering rate, $1/\tau(\omega)$ for four doping levels of $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$. a, $T_c = 67$ K (underdoped); b, 96 K (optimal); c, 82 K (overdoped); d, 60 K (overdoped). e-h, The real part of the optical self-energy, $-2\Sigma_1^{\text{op}}(\omega)$ as defined in Eq. 57. From Ref. (100).

low-energy physics⁽¹⁰⁵⁾¹⁵. We note that whatever the origin of this effect, it is almost certainly the same as that which causes the upturn in the optical scattering rate (9; 96; 100). We should also mention that much of the discussion regarding these self-energies and the like has implicitly assumed that the only possibility of understanding such features are a consequence of some sort of electron-boson coupling, but this is not necessarily the case. There are proposals that purely electronic interactions and proximity to a Mott insulator can give such

¹⁵ My (NPA's) opinion is that these are by and large straw-man arguments and perhaps not the right way to approach the problem of the origin of high- T_c . In a strongly correlated system like the cuprates, it is clear that everything is strongly coupled to everything else. Magnetism is strongly connected to lattice effects and vice versa. In this regard, it is not surprising that experiments sensitive to the lattice show lattice effects and experiments sensitive to magnetism show magnetic effects. One should not expect in such materials that various degrees of freedom neatly partition in separate distinct subsystems.

features (106; 107).

C. Frequency dependent scaling near quantum critical points.

A quantum phase transition (QPT) is a zero-temperature transition between two distinct ground states as a function of a non-thermal parameter, such as magnetic field, pressure, charge density etc. (108; 109). Unlike conventional phase transitions, which are driven by thermal fluctuations, they are driven essentially by diverging fluctuations of the system's zero point motion. Once thought to be only of academic interest, the existence of a QPT nearby in a material's parameter space is believed to influence a whole host of finite temperature properties. QPTs may hold the key to understanding the unusual behavior of many systems at the forefront of condensed matter physics (108).

Just as in the case of conventional phase transitions, QPTs are believed to be characterized by diverging length and time scales if second order. In the disordered state, one envisions an order parameter that fluctuates slower and slower over longer and longer length scales as the transition is approached until at the transition these length and time scales diverge. These length and time scales are the correlation length ξ_c and time τ_c . The divergence of the fluctuation time scales, which in the case of conventional transitions is called *critical slowing down* implies the existence of a characteristic frequency ω_c which vanishes at the transition.

In a QPT, the transition occurs as a function of some non-thermal parameter K . It is usually considered that close to the transition at K_c , ξ_c diverges in a manner $\propto |K - K_c|^{-\nu}$ and τ_c diverges $\propto |K - K_c|^{-z\nu} \sim \xi_c^z$ where ν and z are called the correlation length and dynamic exponent respectively.

From the classical case a well established formalism exists for the understanding of various physical quantities close to continuous (2nd order) transitions. Widom's scaling hypothesis assumes that close to the transition the *only* relevant length and time scales are those associated with diverging correlations in the order parameter (110). Such considerations hold for QPTs also and means that physical observables such as magnetization or conductivity are expected to have scaling forms, in which independent variables such as the temperature, probe frequency or wave vector appear in the argument only as a product with quantities like ξ_c and τ_c . This is expressed formally in terms of *finite-size* scaling. For an incident wave vector $q = 0$ such a scaling form can be written

$$O(K, \omega, T) = \frac{1}{T^{d_o/z}} F(\omega/T, T\tau_c). \quad (63)$$

Here O is some observable and F is the scaling function. d_o is the scaling dimension, which determines how various physical quantities change under a renormaliza-

tion group transformation. It is often close to the “engineering” dimension of the system (for instance 0 for 2D conductivity), but can acquire an anomalous dimension in certain circumstances. Generally one expects frequency and temperature dominated regimes of these response functions for $\omega \gg T, \omega_c$ and $T \gg \omega, \omega_c$ respectively. For further discussion on scaling forms and motivation on this and other related points see the excellent review by Sondhi *et al.* (108).

Scaling functions written as a function of ξ_c and τ_c can be very powerful as they allow the analysis of experimental data independent of microscopic theory. For instance, the scaling exponents ν and z only depend on certain global properties of the system such as symmetry, dimensionality, and the nature of the dominant interactions.

There are many studies where the existence of a QPT is inferred from frequency dependent scaling (see for example (111)) in a regime where frequency effects dominate over temperature ones, but there are far fewer studies where scaling is investigated as one passes through a known QPT. I know of only two where scaling in the frequency dependent conductivity has been investigated. This is unfortunate because, as mentioned, such studies could potentially be tremendously powerful for the investigation of correlated systems where the appropriate underlying physical model is not clear. This shows the extreme experimental challenges inherent in accessing the experimentally relevant frequency and temperature ranges where $\hbar\omega \gg k_B T$ while both $\hbar\omega$ and $k_B T$ are as low as possible, but also below any higher energy scales that are not relevant to the ordered state. Hopefully this situation will change with the increasing prominence and feasibility of broadband microwave and THz techniques.

The first experimental study to investigate frequency dependent scaling near a QPT was that of Engel *et al.* (112), who used a waveguide coplanar transmission setup to perform broadband microwave spectroscopy on quantum Hall systems. In quantum Hall systems the longitudinal resistivity goes to zero at field values where the transverse resistivity assumes perfectly quantized values. Although the value of the Hall resistivity is perfectly quantized, the width of the transition region depends on temperature (113) and on measurement frequency (112). In Fig. 44 the $\text{Re } \sigma_{xx}$ vs. B is shown at three different frequencies and two different temperatures. One can see that at 50 mK, the width of the transitions regions (ΔB) is strongly frequency dependent, while at 470 mK the widths are almost frequency independent.

This frequency and temperature dependence of ΔB (as defined as the extrema of the derivatives of $\text{Re } \sigma_{xx}$) is summarized in Fig. 45 for one of the spin-split levels. Similar data are found for other levels. One sees that for all such levels at low frequencies, the data are frequency independent and temperature dependent, whereas for low temperatures the data are temperature independent and frequency dependent. The crossover between regimes takes place when $3\hbar\omega \sim k_B T$. Such data are consis-

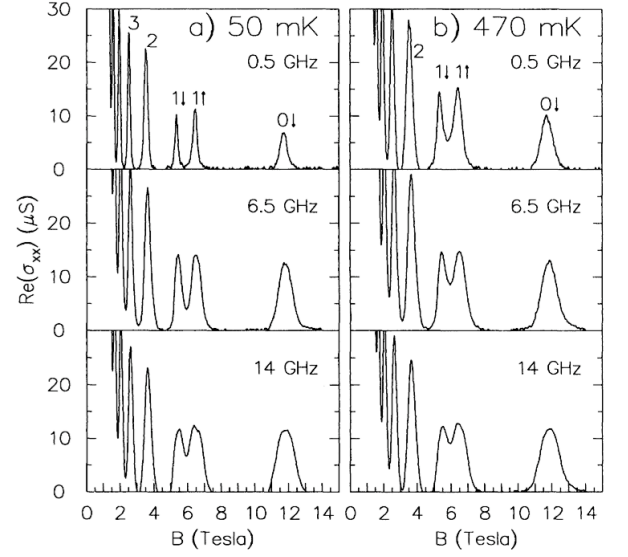


FIG. 44 $\text{Re } \sigma_{xx}$ vs. B at three frequencies and two temperatures. Peaks are marked with Landau level N and spin index.

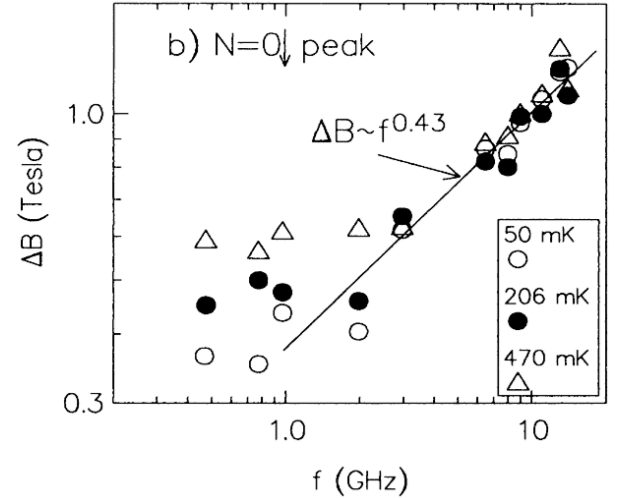


FIG. 45 Peak width between extremal points in longitudinal resistance $d \text{Re } \sigma_{xx} / dB$ ΔB vs. measurement frequency at three different temperatures. Data are shown for the $N = 0 \downarrow$ Landau level.

tent with scaling theories of quantum criticality, where the only relevant frequency scale at the QPT is set by the temperature itself. It is also significant that the crossover condition between frequency and temperature dominated regimes involves $\hbar$, showing that the physics is essentially quantum mechanical. In the high frequency data it is observed that spin split levels give a ΔB which is approximately $\propto \omega^\gamma$, with $\gamma = 0.43$. This is consistent with scaling theories that give an exponent for quantum percolation of $1/\gamma = z\nu = 7/3$ and also consistent with the temperature dependence of these transition widths

as measured by DC transport that show a $T^{\frac{1}{7/3}}$ dependence. It was claimed that through an analysis of both the temperature and frequency dependent exponents, one can extract the dynamic exponent z , which yields $z = 1$. This is consistent with long range Coulomb interaction.

Both the DC data (113) and the high frequency data have transition widths which exhibit a power law dependence on temperature or frequency with an exponent of $3/7$ at all spin-split transitions, showing that all such transitions between quantum Hall levels fall into the same universality class. It should be possible in such a study to incorporate both temperature and frequency dependence into a single scaling function although this has not been done yet. It is expected that a general scaling function of the form

$$\rho(B, T, \omega) = F(\omega/T, \delta/T^{\frac{1}{z\nu}}) \quad (64)$$

applies where $\delta = |B - B_c|/B_c$ measures the distance to the quantum critical point. This function is equivalent to Eq. 63 using the fact that the scaling dimension of the resistivity vanishes in $d = 2$. In the high frequency and high temperature limits, Eq. 64 reduces to one where frequency or temperature appear in the argument as $\frac{\delta}{\omega^{1/z\nu}}$ and $\frac{\delta}{T^{1/z\nu}}$ respectively.

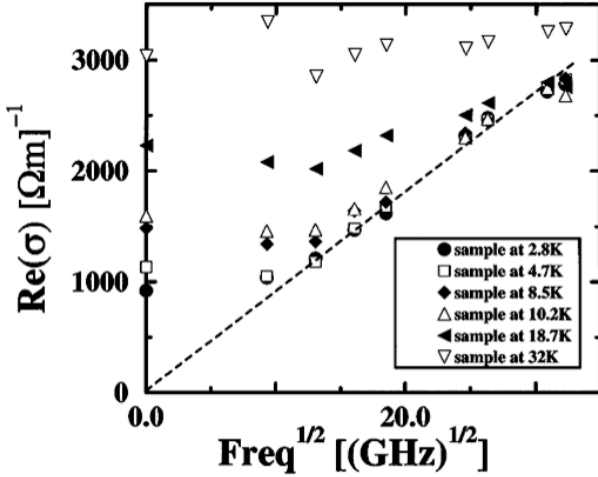


FIG. 46 $\text{Re}\sigma(\omega)$ plotted against $\sqrt{\omega}$ for temperatures 2.8 to 32K and frequencies 87-1040 GHz. For the lowest temperatures and when $\hbar\omega > k_B T$, the data follow a $\sqrt{\omega}$. The data approaches the DC values plotted on the vertical axis for $\hbar\omega \ll k_B T$.

The other frequency dependent study was that of Lee *et al.* (114; 115) who applied the ideas of finite size scaling to the 3D metal-insulator (MI) transition in $\text{Nb}_{1-x}\text{Si}_x$. They measured the frequency dependent conductivity *via* millimeter wave transmission through thin films whose relative concentrations of Nb to Si were tuned exactly to the MI QPT point at x_c . As in the study of Engel *et al.* (112), for samples tuned right to quantum

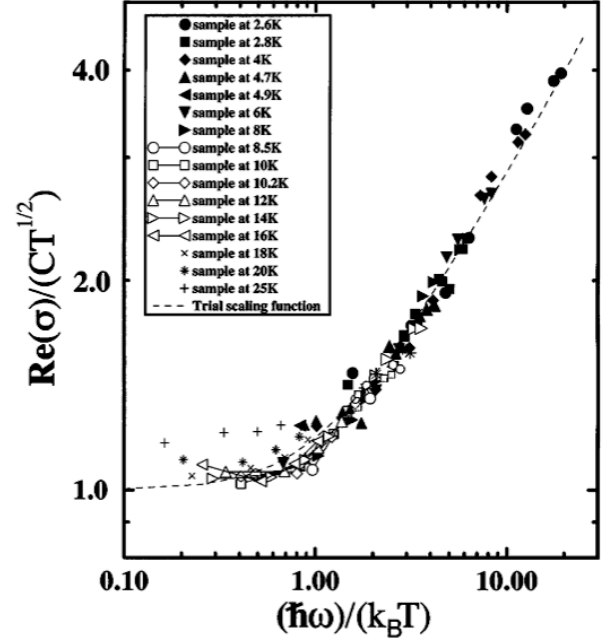


FIG. 47 Log-log plot of conductivity scaled by the factor $C = 475(\Omega\text{mK}^{1/2})^{-1}$ vs. ω/T . For temperatures 16 K and below, the data for the entire experimental frequency range collapse onto a single curve within the experimental noise. Higher temperature data begin to rise above the collapsed data systematically for low scaled frequencies. The dashed line is a trial scaling function as described in the text.

criticality it is observed that for the $\hbar\omega \gg k_B T$ data the conductivity is temperature independent and that for $\hbar\omega \ll k_B T$, the data are frequency independent (Fig. 46). A crossover from a frequency dominated regime to a temperature dominated regime implies the existence of a scaling function Σ of a form that can be inferred from above Eq. 63

$$\sigma(x_c, T, \omega) = CT^{\frac{1}{z}} \Sigma\left(\frac{\hbar\omega}{k_B T}\right). \quad (65)$$

In previous work on similar samples it was found that for samples tuned to the critical concentration the DC conductivity followed a $T^{1/2}$ relation implying $z = 2$. As shown in Fig. 47, successful scaling can be found by plotting the scaled conductivity $\text{Re}\sigma(T, \omega)/CT^{1/z}$ using this z . This procedure collapses the data over the entire measured frequency range for temperatures 16 K and below, implying the applicability of a scaling function that depends *only* on the scaled frequency. Data for temperatures higher than 16 K starts to rise above the other collapsed curves, indicating the appearance of other mechanisms (electron-phonon scattering for example) which limits the size of quantum fluctuations. This is consistent with the DC result where the conductivity starts to deviate from the $T^{\frac{1}{2}}$ above 16 K.

As already inferred from Fig. 46, the scaling function shows both temperature and frequency dominated regimes, with a crossover at approximately $\hbar\omega \sim k_B T$. Again, this shows that at the QPT the only energy scale is set by the temperature itself. Note, that this crossover happens at a slightly different ω/T ratio than the quantum Hall case, but is still of order unity as expected. For high frequencies the scaling function follows a power law dependence with the same exponent as was used to scale the vertical axis with $z = 2$. This means that an equivalent scaling function could have been found by dividing the conductivity data by $\omega^{\frac{1}{2}}$ and plotting the data as a function of T/ω . Lee *et al.* (114) attempted to guess the form of the scaling function with the expression $\Sigma = \text{Re}(1 - i\hbar\omega/k_B T)^{1/2}$. The function successfully captures the high and low ω/T , but misses the sharp crossover near $\hbar\omega/k_B T \sim 1$.

The value of the dynamic exponent $z = 2$, which was found in this study is interesting. It is different than what is expected from models without a density of states singularity, where $z = d$ or for those with straight Coulomb interaction ($z = 1$ observed in the quantum Hall case). However, it is consistent with several field-theoretic scenarios which give $z = 2$ (116).

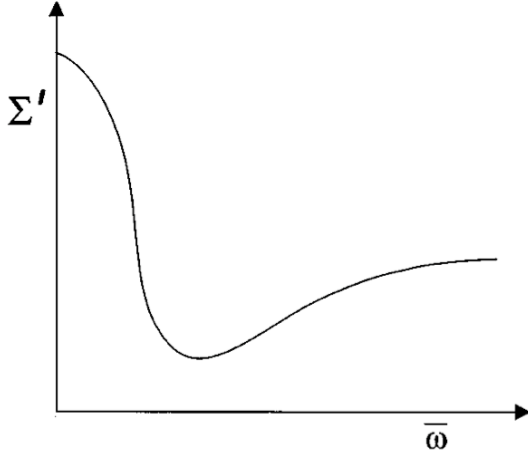


FIG. 48 The real part of universal scaling function Σ , as a function of $\bar{\omega} = \omega/T$. There is a Drude-like peak from the inelastic scattering between thermally exciting carrier, which falls off at order $\bar{\omega} \sim 1$. At larger $\bar{\omega}$ there is a crossover to a collisionless regime. Importantly the function gives different values in the $\bar{\omega} \rightarrow 0$ and $\bar{\omega} \rightarrow \infty$ limits.

I should mention that as presented above, frequency scaling does not necessarily give us any information on exponents etc. that we could not also get from the temperature scaling. Here the primary importance of frequency scaling was in its ability to demonstrate how characteristic time scales diverge at the QPT, which leaves the temperature itself as the only energy scale in the problem. However, as discussed by Damle and Sachdev (117), the fact that at the QPT itself, response functions can be written as a universal function of ω/T , means

that one does not necessarily expect the same behavior in the $\omega = 0, T \rightarrow 0$ (incoherent) limit as in the $\omega \rightarrow 0, T = 0$ (phase-coherent) limit. Since all DC experiments are in the former limit, while the vast majority of theoretical predictions are in the latter, finite frequency measurements can in fact give unique insight. It was predicted by Damle and Sachdev that at the 2D superfluid-insulator transition the conductivity is equal to two different universal numbers of order e^2/h in the $\omega/T \rightarrow 0$ and $\omega/T \rightarrow \infty$ limits as shown in Fig. 48. This is true even if ω and T are both asymptotically small.

VI. ACKNOWLEDGMENTS

I would like to thank the organizers of the 2008 Boulder School for Condensed Matter Physics for the opportunity to talk about these topics. I'd also like to thank Luke Bilbro, Vladimir Cvetkovic, Natalia Driehko, and Wei Liu for helpful suggestions and careful reading of these lecture notes.

References

- [1] F. Wooten, "Optical Properties of Solids", (Academic Press, New York, 1972).
- [2] M. Dressel and G. Grüner, "Electrodynamics of Solids: Optical Properties of Electrons in Matter", (Cambridge University Press, 2002).
- [3] G. D. Mahan, "Many-Particle Physics", (Plenum, 2nd ed., 1990).
- [4] Richard D. Mattuck, "A Guide to Feynman Diagrams in the Many-Body Problem", (Dover, 2nd ed., 1992).
- [5] M. Tinkham, "Introduction to Superconductivity", (2nd Ed., McGraw-Hill, NY, 1996).
- [6] E. van Heumen and D. van der Marel, "Salerno lectures: Optical probes of electron correlations in solids", Lecture notes for "XI Training Course in the Physics of Strongly Correlated Systems", Vietri sul Mare, Italy, 2-13 October 2006. Published in Lectures On The Physics Of Strongly Correlated Systems XI: Eleventh Training Course in the Physics of Strongly Correlated Systems Editors F. Mancini and A. Avella. AIP Conference Proceedings 918 ISBN:978-0-7354-0428-1 (2006); Available at http://optics.unige.ch/vdm/marel_files/salerno_lectures.pdf
- [7] D. van der Marel, "Title: Optical signatures of electron correlations in the cuprates", "Strong Interactions in Low Dimensions, Series: Physics and Chemistry of Materials with Low-Dimensional Structures" Vol. 25, pp. 237-276, Dionys Baeriswyl (Editor), L. Degiorgi (Editor), Springer (2004); Available at <http://arxiv.org/abs/cond-mat/0301506>.
- [8] Andrew Millis, "Optical conductivity and correlated electron physics", "Strong interactions in low dimensions, Series: Physics and Chemistry of Materials with Low-Dimensional Structures" Vol. 25, pp. 195-235 (2004), Dionys Baeriswyl (Editor), L. Degiorgi (Editor), Springer (2004); Available at <http://phys.columbia.edu/~millis/july20.pdf>.

- [9] D. Basov and T. Timusk, “Electrodynamics of high- T_c superconductors”, *Reviews of Modern Physics* **77**, 721 (2005).
- [10] L. Degiorgi, “The electrodynamic response of heavy-electron compounds”, *Rev. Mod. Phys.* **71**, 687 (1999).
- [11] A. Millis and P.A. Lee, “Large-orbital-expansion for the lattice Anderson model”, *Phys. Rev. B* **35**, 3394 (1987).
- [12] C.C. Homes, “Fourier Transform Infrared Spectroscopy”, Lecture notes available here <http://infrared.phy.bnl.gov/pdf/homes/fir.pdf>
- [13] George B. Arfken and Hans J. Weber, “Mathematical Methods for Physicists” (Academic Press, 2005).
- [14] John David Jackson, “Classical Electrodynamics” (3rd ed., Wiley, 1998).
- [15] Thomas P. Devereaux and Rudi Hackl, “Inelastic light scattering from correlated electrons”, *Rev. Mod. Phys.* **79**, 175 (2007).
- [16] L.D. Landau, *Sov. Phys. JETP* **3**, 920 (1956); **5**, 101 (1957).
- [17] D.C. Tsui, H.L. Stormer and A.C. Gossard, “Two-Dimensional Magnetotransport in the Extreme Quantum Limit”, *Phys. Rev. Lett.* **48**, 1559 (1982).
- [18] R.B. Laughlin, “Anomalous Quantum Hall Effect: An Incompressible Quantum Fluid with Fractionally Charged Excitations”, *Phys. Rev. Lett.* **50**, 1395 (1983).
- [19] E. Lieb and F.Y. Wu, “Absence of Mott Transition in an Exact Solution of the Short-Range, One-Band Model in One Dimension”, *Phys. Rev. Lett.* **20**, 1445 (1968).
- [20] A. Schwartz *et al.*, “On-chain electrodynamics of metallic (TMTSF)₂X salts: Observation of Tomonaga-Luttinger liquid response”, *Phys. Rev. B* **58**, 1455 (1998).
- [21] M. Bockrath *et al.*, “Luttinger-liquid behavior in carbon nanotubes”, *Nature* **397**, 598 (1999).
- [22] R. Egger and A.O. Gogolin, “Bulk and Boundary Zero-Bias Anomaly in Multiwall Carbon Nanotubes”, *Phys. Rev. Lett.* **87**, 066401 (2001).
- [23] L. Degiorgi *et al.*, “The Electrodynamic Response of Heavy-Electron Materials with Magnetic Phase Transitions”, *Z. Phys. B* **102**, 367M (1997).
- [24] Stefan J. Turneaure, Aaron A. Pesetski, and Thomas R. Lemberger, “Numerical modeling and experimental considerations for a two-coil apparatus to measure the complex conductivity of superconducting films”, *J. Appl. Phys.* **83**, 4334 (1998).
- [25] O. Klein, S. Donovan, M. Dressel, G. Grüner, *Int. J. Infrared Millim. Waves* **14**, 2423 (1993).
- [26] Marc Scheffler, Martin Dressel, Martin Jourdan and Hermann Adrian, “Extremely slow Drude relaxation of correlated electrons”, *Nature* **438**, 1135 (2005).
- [27] Marc Scheffler and Martin Dressel, “Broadband microwave spectroscopy in Corbino geometry for temperatures down to 1.7 K”, *Rev. Sci. Instrum.* **76**, 074702 (2005).
- [28] James C. Booth, Dong Ho Wu, S. B. Qadri, E. F. Skelton, M. S. Osofsky, Alberto Piqué, and Steven M. Anlage, “Large Dynamical Fluctuations in the Microwave Conductivity of YBa₂Cu₃O_{7- δ} above T_c ”, *Phys. Rev. Lett.* **77**, 4438 (1996).
- [29] J. C. Booth, Dong Ho Wu, and Steven M. Anlage, “A broadband method for the measurement of the surface impedance of thin films at microwave frequencies”, *Rev. Sci. Instrum.* **65**, 2082 (1994).
- [30] M. L. Stutzman, Mark Lee, R. F. Bradley, “Broadband calibration of long lossy microwave transmission lines at cryogenic temperatures using nichrome films”, *Rev. Sci. Instrum.* **71**, 4596 (2000).
- [31] M. Lee and M. L. Stutzmann, “Microwave ac Conductivity Spectrum of a Coulomb Glass”, *Phys. Rev. Lett.* **87**, 056402 (2001).
- [32] P. J. Turner, D. M. Broun, Saeid Kamal, M. E. Hayden, J. S. Bobowski, R. Harris, D. C. Morgan, J. S. Preston, D. A. Bonn, and W. N. Hardy, “Bolometric technique for high-resolution broadband microwave spectroscopy of ultra-low-loss samples”, *Rev. Sci. Instrum.* **75**, No. 1, January (2004).
- [33] G. Grüner, *Waveguide Configuration Optical Spectroscopy, in Millimeter and Submillimeter Wave Spectroscopy of Solids*, edited by G. Grner, Series: Topics in Applied Physics, Vol. No. 74, Ch. 4., 111-166, Springer Verlag, Berlin.
- [34] <http://www.er.doe.gov/bes/reports/abstracts.html#THz>
- [35] R. A. Kaindl, M. A. Carnahan, D. Hägele, R. Löwenich and D. S. Chemla, “Ultrafast terahertz probes of transient conducting and insulating phases in an electron-hole gas”, *Nature* **423**, 734 (2003).
- [36] James N. Heyman, Roland Kersting and Karl Unterrainer, “Time-domain measurement of intersubband oscillations in a quantum well”, *Appl. Phys. Lett.* **72**, 644 (1998).
- [37] A. J. Gatesman, J. Waldman, M. Ji, C. Musante, and S. Yngvesson, “An anti-reflection coating for silicon optics at terahertz frequencies”, *IEEE Microwave Guid. Wave Lett.* **10**, 264-266 (2000).
- [38] J. S. Dodge, C. P. Weber, J. Corson, J. Orenstein, Z. Schlesinger, J. W. Reiner, M. R. Beasley, “Low-Frequency Crossover of the Fractional Power-Law Conductivity in SrRuO₃”, *Phys. Rev. Lett.* **85**, 4932 - 4935 (2000).
- [39] J. Corson, R. Mallozzi, J. Orenstein, J. N. Eckstein and I. Bozovic, “Vanishing of phase coherence in underdoped Bi₂Sr₂CaCu₂O_{8+ δ} ”, *Nature* **398**, 221 (1999).
- [40] S. Wang, B. Ferguson, D. Abbott and X.-C. Zhang, “T-ray imaging and tomography,” *J. Bio. Phys.* **29**, 247-256 (2004).
- [41] Michael Nagel, Peter Haring Bolivar, Martin Brucherseifer, Heinrich Kurz, Anja Bosserhoff, and Reinhard Büttner, “Integrated Planar Terahertz Resonators for Femtomolar Sensitivity Label-Free Detection of DNA Hybridization”, *Appl. Opt.* **41**, 2074-8 (2002).
- [42] B.B. Hu and M.C. Nuss, “Imaging with terahertz waves”, *Opt. Lett.* **20**, 1716 (1995).
- [43] X.-C. Zhang, “Terahertz wave imaging: horizons and hurdles”, *Physics in Medicine and Biology* **47**, 1 (2002).
- [44] J. L. Johnson, T. D. Dorney, and D. M. Mittleman, “Enhanced depth resolution in terahertz imaging using phase-shift interferometry”, *Applied Physics Letters* **78**, 835 (2001).
- [45] http://en.wikipedia.org/wiki/Terahertz_time-domain_spectroscopy.
- [46] D. van Mechelen *et al.*, to be submitted *App. Phys. Lett.*
- [47] G.V. Kozlov and V.V. Volkov, in *Millimeter and Submillimeter Wave Spectroscopy of Solids*, edited by G. Grner (Springer, Berlin, 1998).
- [48] W. J. Padilla, Z. Q. Li, K. S. Burch, Y. S. Lee, K. J. Mikolaitis, and D. N. Basov, “Broadband multi-interferometer spectroscopy in high magnetic fields:

- From THz to visible”, Review of Scientific Instruments **75**, 4710 (2004).
- [49] <http://en.wikipedia.org/wiki/Spectrometer>
- [50] D.E. Aspnes, Surf. Sci. **37**, 418 (1973).
- [51] D.E. Aspnes and A.A. Studna. Phys. Rev. B **27**, 985 (1983).
- [52] A. Röseler. Infrared Spectroscopic Ellipsometry, Akademie-Verlag, Berlin (1990).
- [53] K.L. Barth *et al.*, Thin Solid Films **234**, 314 (1993).
- [54] J. Bremer, O. Hunderi, K. Faping, T. Skauli and E. Wold, Appl. Optics **31**, 471(1992).
- [55] C. Bernhard, J. Humlicek and B. Keimer, “Far-infrared ellipsometry using a synchrotron light source the dielectric response of the cuprate high T_c superconductors”, Thin Solid Films **455-456**, 143-149, (2004).
- [56] A.B. Kuzmenko, “Kramers-Kronig constrained variational analysis of optical spectra”, Rev. Sci. Instrum. **76**, 083108 (2005).
- [57] M. Bass and E.W. Van Stryland, (eds.) Handbook of Optics vol. 2 (2nd ed.), McGraw-Hill (1994).
- [58] P. B. Johnson and R. W. Christy, “Optical Constants of the Noble Metals”, Phys. Rev. B **6**, 4370 - 4379 (1972).
- [59] H. Ehrenreich, H. R. Philipp, and B. Segall, “Optical Properties of Aluminum”, Phys. Rev. **132**, 1918 - 1928 (1963).
- [60] H. Ehrenreich and H.R. Philipp, “Optical Properties of Ag and Cu”, Phys. Rev. **128**, 1622 (1962).
- [61] D. M. Roessler and W. C. Walker, “Electronic Spectra of Crystalline NaCl and KCl”, Phys. Rev. **166**, 599 - 606 (1968).
- [62] A. Damascelli, K. Schulte, D. van der Marel, and A.A. Menovsky, “Infrared spectroscopic study of phonons coupled to charge excitations in FeSi”, Phys. Rev. B **55**, R4863 (1997).
- [63] G. A. Thomas, M. Capizzi, F. DeRosa, R. N. Bhatt, and T. M. Rice, “Optical study of interacting donors in semiconductors”, Phys. Rev. B **23**, 5472 - 5494 (1981).
- [64] E. Helgren, N.P. Armitage, G. Grüner, “Electrodynamics of a Coulomb Glass in n-Type Silicon”, Phys. Rev. Lett. **89**, 246601 (2002).
- [65] E. Helgren, N. P. Armitage, and G. Grüner, “Frequency-dependent conductivity of electron glasses”, Phys. Rev. B **69**, 014201 (2004).
- [66] N.F. Mott, J. Non-Cryst. Solids **1**, 1 (1968).
- [67] A.L. Efros and B.I. Shklovskii, J. Phys. C **8**, L49 (1975).
- [68] M. Lee and M.L. Stutzmann, “Microwave ac Conductivity Spectrum of a Coulomb Glass”, Phys. Rev. Lett. **87**, 056402 (2001).
- [69] R.N. Bhatt *private communication*.
- [70] P.W. Anderson, Comments Solid State Phys. **2**, 193 (1970).
- [71] M.B.J. Meinders *et al.*, “Spectral-weight transfer: Breakdown of low-energy-scale sum rules in correlated systems”, Phys. Rev. B **48**, 3916 (1993).
- [72] S. Uchida *et al.*, “Optical spectra of $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$: Effect of carrier doping on the electronic structure of the CuO_2 plane”, Phys. Rev. B **43**, 7942 (1991).
- [73] L. C. Hebel and C. P. Slichter, “Nuclear Relaxation in Superconducting Aluminum”, Phys. Rev. **107**, 901 - 902 (1957).
- [74] Leigh Hunt Palmer and M. Tinkham, “Far-Infrared Absorption in Thin Superconducting Lead Films”, Phys. Rev. **165**, 588 - 595 (1968).
- [75] O. Klein, E. J. Nicol, K. Holczer and G. Grüner, “Conductivity coherence factors in the conventional superconductors Nb and Pb”, Phys. Rev. B **50**, 6307 - 6316 (1994).
- [76] A. Hosseini *et al.*, “Survival of the d-Wave Superconducting State near the Edge of Antiferromagnetism in the Cuprate Phase Diagram”, Phys. Rev. Lett. **93**, 107003 (2004).
- [77] D. A. Bonn, P. Dosanjh, R. Liang, and W. N. Hardy, “Evidence for rapid suppression of quasiparticle scattering below T_c in $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ ”, Phys. Rev. Lett. **68**, 2390 - 2393 (1992).
- [78] G. Grüner, “Density Waves in Solids”, Westview Press (January 15, 2000).
- [79] D. Y. Smith, E. Shiles, “Finite-energy f-sum rules for valence electrons”, Phys. Rev. B **17**, 4689 (1978).
- [80] H.J.A. Molegraaf, C. Presura, D. van der Marel, P. H. Kes, and M. Li, “Superconductivity Induced Transfer of In-Plane Spectral Weight in $\text{BiSr}_2\text{CaCu}_2\text{O}_{8+\delta}$ ”, Science **295**, 2239 (2002).
- [81] A.V. Boris, N. N. Kovaleva, O. V. Dolgov, T. Holden, C. T. Lin, B. Keimer, and C. Bernhard, “The in-plane spectral weight of charge carriers in $\text{YBa}_2\text{Cu}_3\text{O}_{6.9}$: Evidence against kinetic energy driven pairing”, Science **304**, (2004).
- [82] P. Nozières and D. Pines, “Correlation Energy of a Free Electron Gas”, Phys. Rev. **111**, 442 - 454 (1958).
- [83] P. Nozières and D. Pines, “Electron Interaction in Solids. Characteristic Energy Loss Spectrum”, Phys. Rev. **113**, 1254 - 1267 (1959).
- [84] Misha Turlakov and Anthony J. Leggett, “Sum rule analysis of umklapp processes and Coulomb energy: Application to cuprate superconductivity”, Phys. Rev. B **67**, 094517 (2003).
- [85] Misha Turlakov, “Umklapp scattering in cuprates”, J. Phys. A: Math. Gen. **36**, 93999404 (2003).
- [86] E. Shiles, Taizo Sasaki, Mitio Inokuti, and D. Y. Smith, “Self-consistency and sum-rule tests in the Kramers-Kronig analysis of optical data: Applications to aluminum”, Phys. Rev. B **22**, 1612 (1980).
- [87] M. Altarelli, D. L. Dexter, H. M. Nussenzweig, and D. Y. Smith, Phys. Rev. B **6**, 4502 (1972).
- [88] M. Altarelli and D. Y. Smith, Phys. Rev. B **9**, 1290 (1974).
- [89] J. W. Allen and J. C. Mikkelsen, “Optical properties of CrSb, MnSb, NiSb, and NiAs”, Phys. Rev. B **15**, 2952 - 2960 (1977).
- [90] S.J. Youn, phys. stat. sol. (b) **4**, 13541362 (2007).
- [91] P.B. Allen, “Electron-Phonon Effects in the Infrared Properties of Metals”, Phys. Rev. B **3**, 305 (1971).
- [92] R. R. Joyce and P. L. Richards, “Phonon Contribution to the Far-Infrared Absorptivity of Superconducting and Normal Lead”, Phys. Rev. Lett. **24**, 1007 - 1011 (1970).
- [93] A. M. Awasthi, L. Degiorgi, G. Grüner, Y. Dalichaouch, and M. B. Maple, “Complete optical spectrum of CeAl_3 ”, Phys. Rev. B **48**, 10692, (1993).
- [94] A. V. Puchkov, D. N. Basov, and T. Timusk, J. Phys.: Condens. Matter **8**, 10049-10082, (1996).
- [95] F. Marsiglio, J. P. , and E. Schachinger, “Sum rule for optical scattering rates”, Phys. Rev. B **65**, 014515 (2001).
- [96] J. Carbotte, E. Schachinger, and D. N. Basov, “Coupling strength of charge carriers to spin fluctuations in high-temperature superconductors”, Nature (London)

- 401**, 354 (1999).
- [97] R. Tediosi *et al.*, “Charge Carrier Interaction with a Purely Electronic Collective Mode: Plasmarons and the Infrared Response of Elemental Bismuth”, *Phys. Rev. Lett.* **99**, 016406 (2007).
 - [98] B. Lundqvist, *Phys. Kondens. Mater.* **6**, 193 (1967).
 - [99] B. Lundqvist, *Phys. Status Solidi* **32**, 273 (1969).
 - [100] J. Hwang, T. Timusk, and G. D. Gu, “High-transition-temperature superconductivity in the absence of the magnetic resonance mode”, *Nature* **427**, 714 (2004)
 - [101] A. Kaminski *et al.*, “Renormalization of Spectral Line Shape and Dispersion below T_c in $Bi_2Sr_2CaCu_2O_{8+\delta}$ ”, *Phys. Rev. Lett.* **86**, 1070–1073 (2001).
 - [102] P.D. Johnson *et al.*, Doping and Temperature Dependence of the Mass Enhancement Observed in the Cuprate $Bi_2Sr_2CaCu_2O_{8+\delta}$, *Phys. Rev. Lett.* **87**, 177007 (2001).
 - [103] J.M. Rossat-Mignod *et al.*, “Neutron scattering study of the $YBa_2Cu_3O_{6+x}$ system”, *Physica C* **86**, 86-92 (1991).
 - [104] H.A. Mook *et al.*, “Polarized neutron determination of the magnetic excitations in $YBa_2Cu_3O_7$ ”, *Phys. Rev. Lett.* **70**, 3490–3493 (1993).
 - [105] A. Lanzara *et al.*, “Evidence for Ubiquitous Electron-Phonon Coupling in High Temperature Superconductors”, *Nature* **412**, 510-514 (2001).
 - [106] Shiladitya Chakraborty, Dimitrios Galanakis, Philip Phillips, “Kinks and Mid-Infrared Optical Conductivity from Strong Electron Correlation”, arXiv:0712.2838v1.
 - [107] K. Byczu, M. Kolla, K. Hel, Y.-F. Yan, I. A. Nekraso, Th. Pruschke and D. Vollhardt, “Kinks in the dispersion of strongly correlated electrons”, *Nature Physics* **3**, 168-171 (2007).
 - [108] S. L. Sondhi *et al.*, “Continuous quantum phase transitions”, *Rev. Mod. Phys.* **69**, 315 (1997).
 - [109] S. Sachdev, *Quantum Phase Transitions*, Cambridge University Press (1999).
 - [110] H. E. Stanley, *Introduction to Phase Transitions and Critical Phenomena* Oxford University Press, Oxford, 1971.
 - [111] D. van der Marel *et al.*, “Quantum critical behaviour in a high-Tc superconductor”, *Nature* **425**, 271-274 (18 September 2003).
 - [112] L.W. Engel, D. Shahar, C. Kurdak, and D.C. Tsui, “Microwave frequency dependence of integer quantum Hall effect: Evidence for finite-frequency scaling”, *Phys. Rev. Lett.* **71**, 2638 (1993).
 - [113] H.P. Wei, D.C. Tsui, M.A. Paalanen, and A.M.M. Pruisken, “Experiments on Delocalization and Universality in the Integral Quantum Hall Effect”, *Phys. Rev. Lett.* **61**, 1294. (1988).
 - [114] H.-L. Lee, J. P. Carini, D. V. Baxter, G. Grüner, “Temperature-Frequency Scaling in Amorphous Niobium-Silicon near the Metal-Insulator Transition”, *Phys. Rev. Lett.* **80**, 4261-4264 (1998).
 - [115] H.-L. Lee, J.P. Carini, D.V. Baxter, W. Henderson, and G. Grüner, “Quantum-Critical Conductivity Scaling for a Metal-Insulator Transition”, *Science* **287**, 633-6 (2000).
 - [116] D. Belitz and T. R. Kirkpatrick, “The Anderson-Mott transition”, *Rev. Mod. Phys.* **66**, 261 (1994).
 - [117] Kedar Damle and Subir Sachdev, “Nonzero-temperature transport near quantum critical points”, *Phys. Rev. B* **56**, 8714 (1997).